

P&S Processing-in-Memory

Real-World Processing-in-Memory Architectures:
Alibaba Hybrid Bonding PNM Engine

Dr. Juan Gómez Luna

Prof. Onur Mutlu

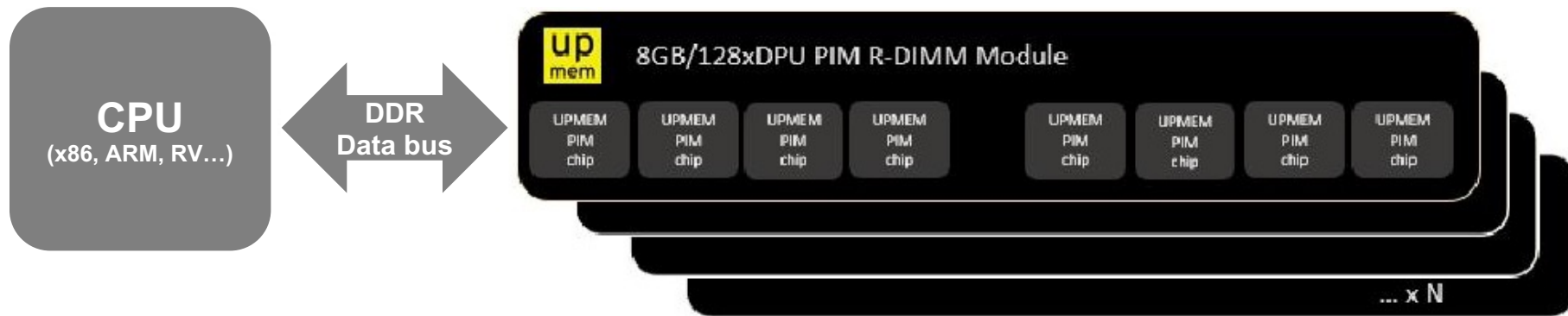
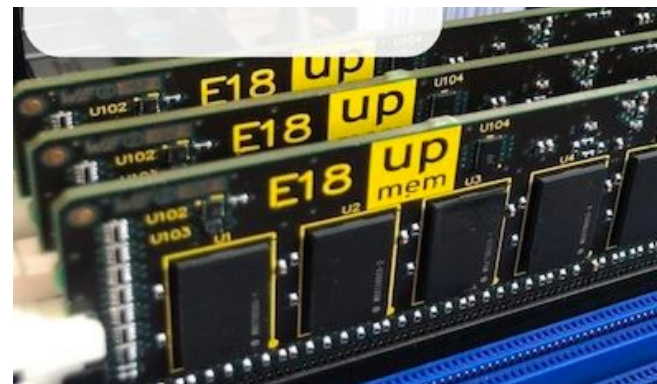
ETH Zürich

Fall 2022

29 November 2022

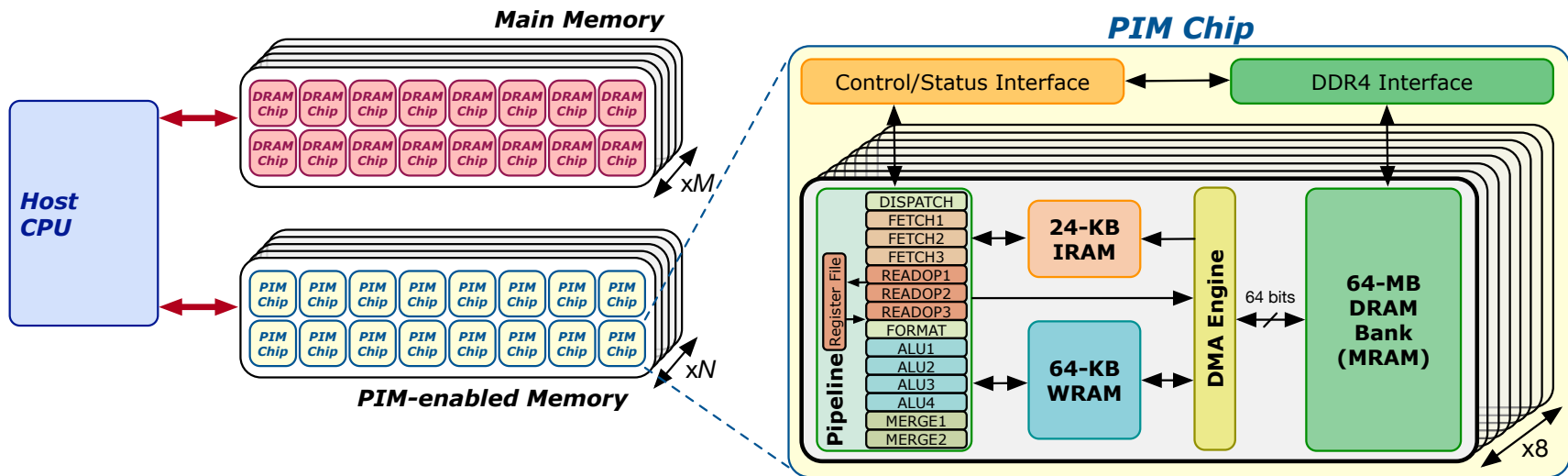
UPMEM Processing-in-DRAM Engine (2019)

- **Processing in DRAM Engine**
- Includes **standard DIMM modules**, with a **large number of DPU processors** combined with DRAM chips.
- Replaces **standard DIMMs**
 - DDR4 R-DIMM modules
 - 8GB+128 DPUs (16 PIM chips)
 - Standard 2x-nm DRAM process
 - **Large amounts of** compute & memory bandwidth



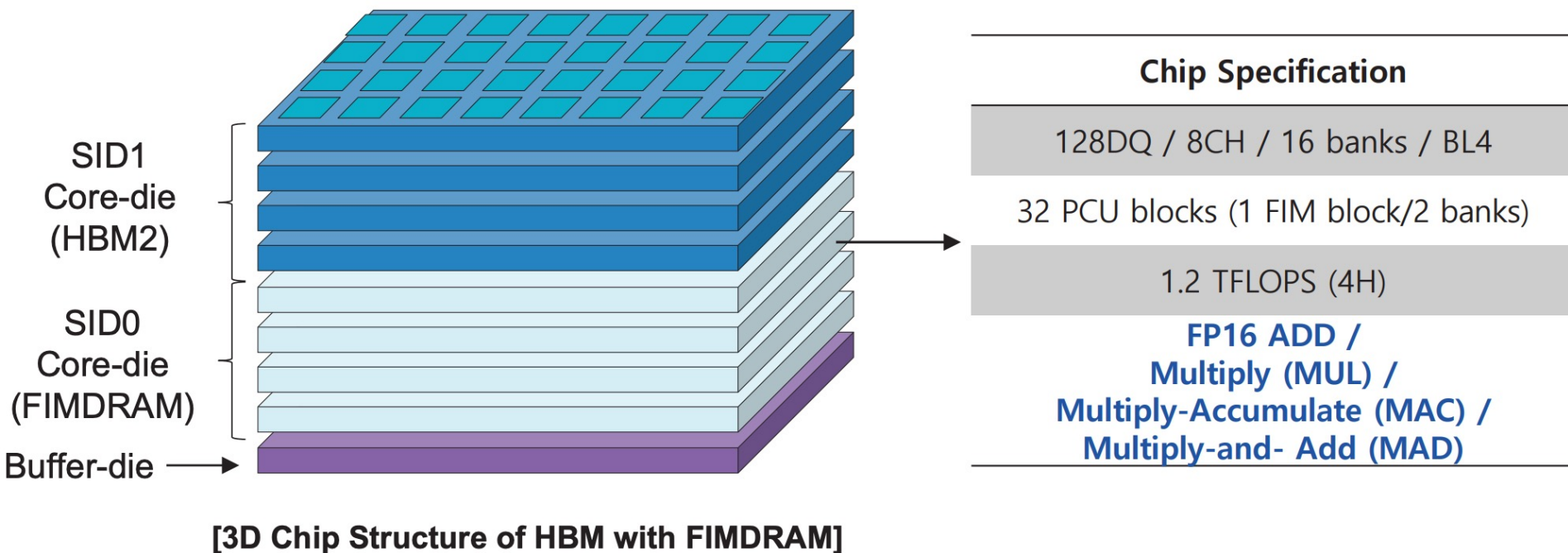
UPMEM PIM System Organization

- A UPMEM DIMM contains 8 or 16 chips
 - Thus, 1 or 2 ranks of 8 chips each
- Inside each PIM chip there are:
 - 8 64MB banks per chip: Main RAM (MRAM) banks
 - 8 DRAM Processing Units (DPUs) in each chip, 64 DPUs per rank



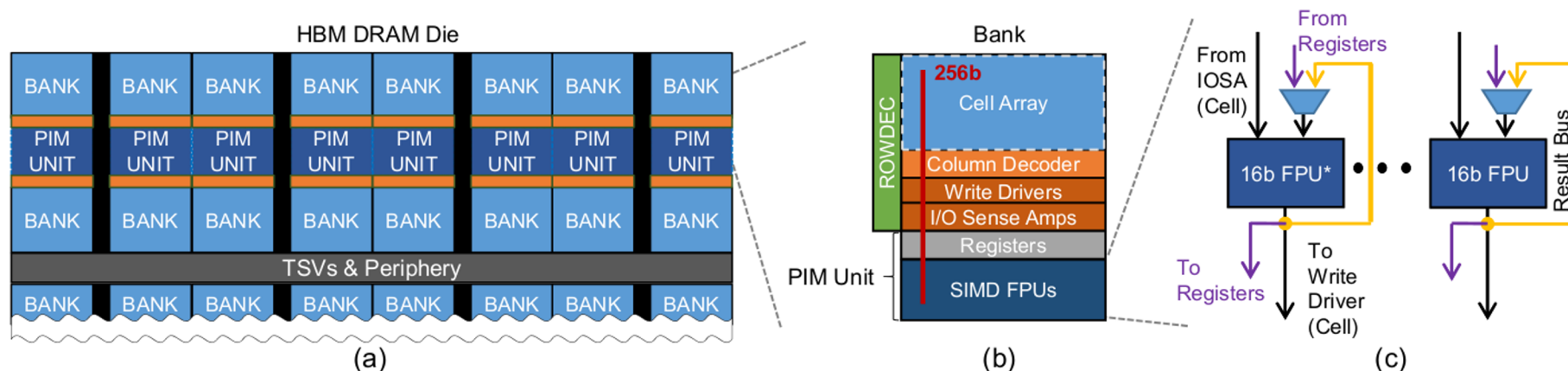
FIMDRAM: Chip Structure

■ FIMDRAM based on HBM2



FIMDRAM: System Organization (III)

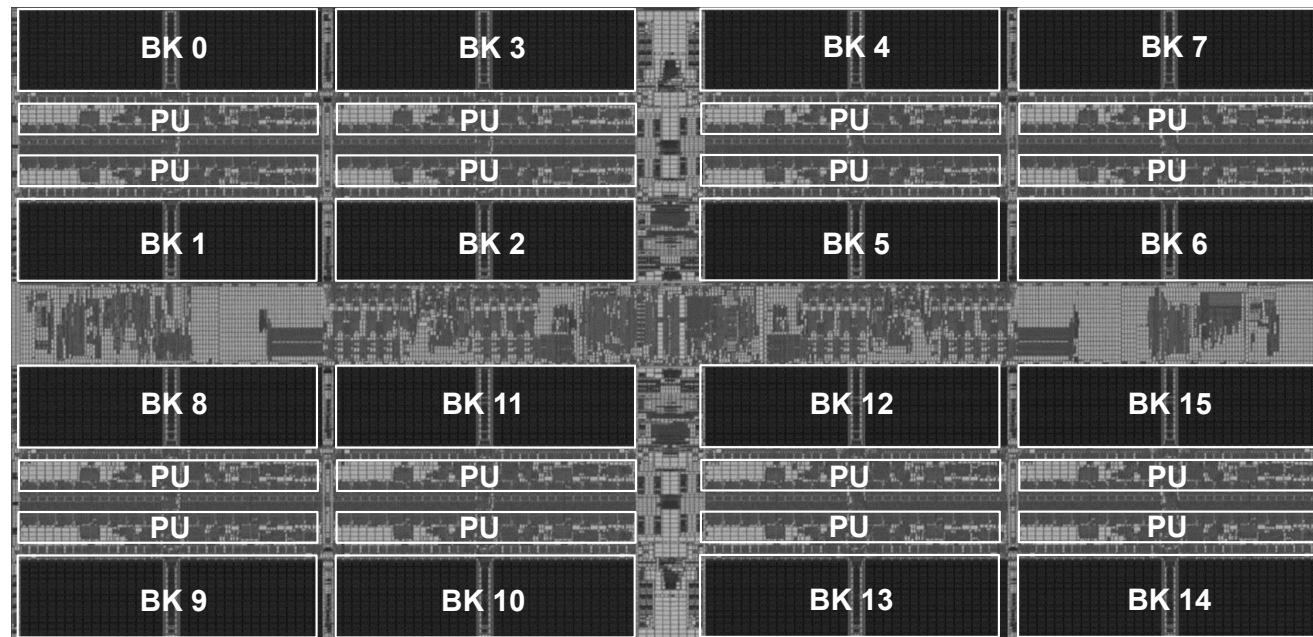
- PIM units respond to standard DRAM column commands (RD or WR)
 - Compliant with **unmodified JEDEC controllers**
- They execute **one wide-SIMD operation** commanded by a **PIM instruction with deterministic latency in a lock-step manner**
- A PIM unit can get **16 16-bit operands** from IOSAs, a register, and/or the result bus



AiM: Chip Implementation

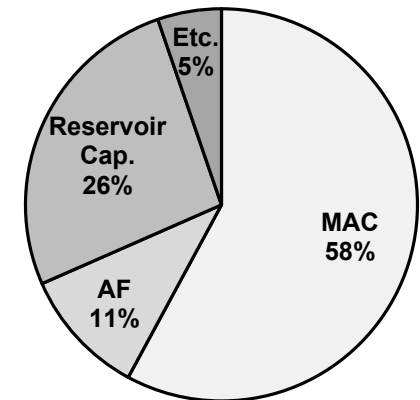
- 4 Gb AiM die with 16 processing units (PUs)

AiM Die Photograph



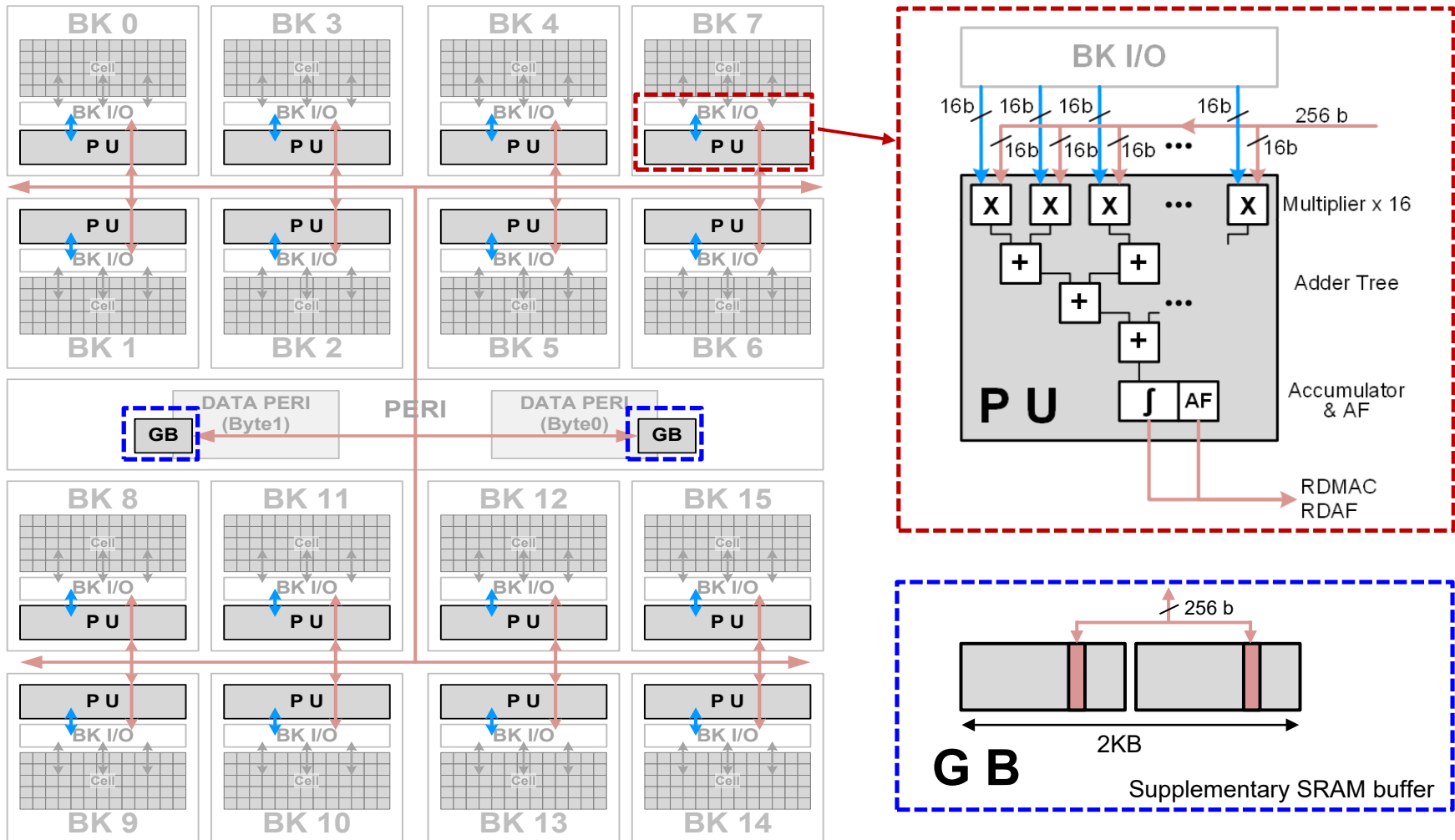
1 Process Unit (PU) Area

Total	0.19mm ²
MAC	0.11mm ²
Activation Function (AF)	0.02mm ²
Reservoir Cap.	0.05mm ²
Etc.	0.01mm ²



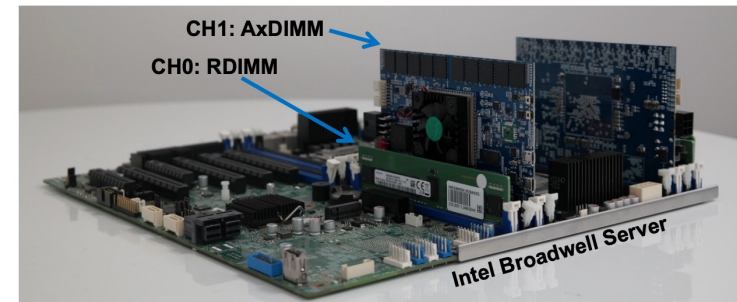
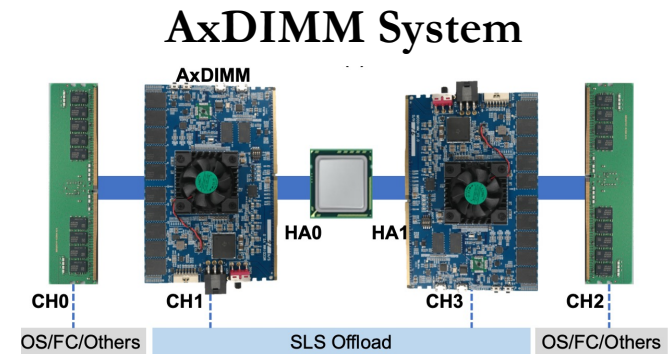
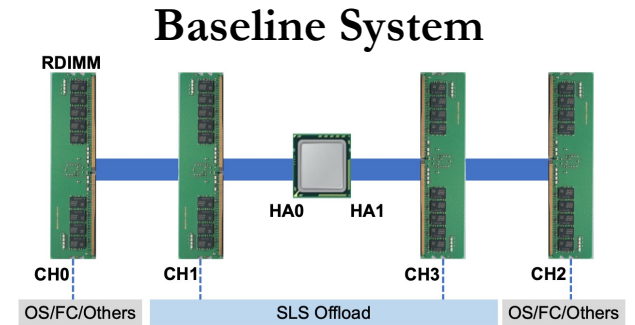
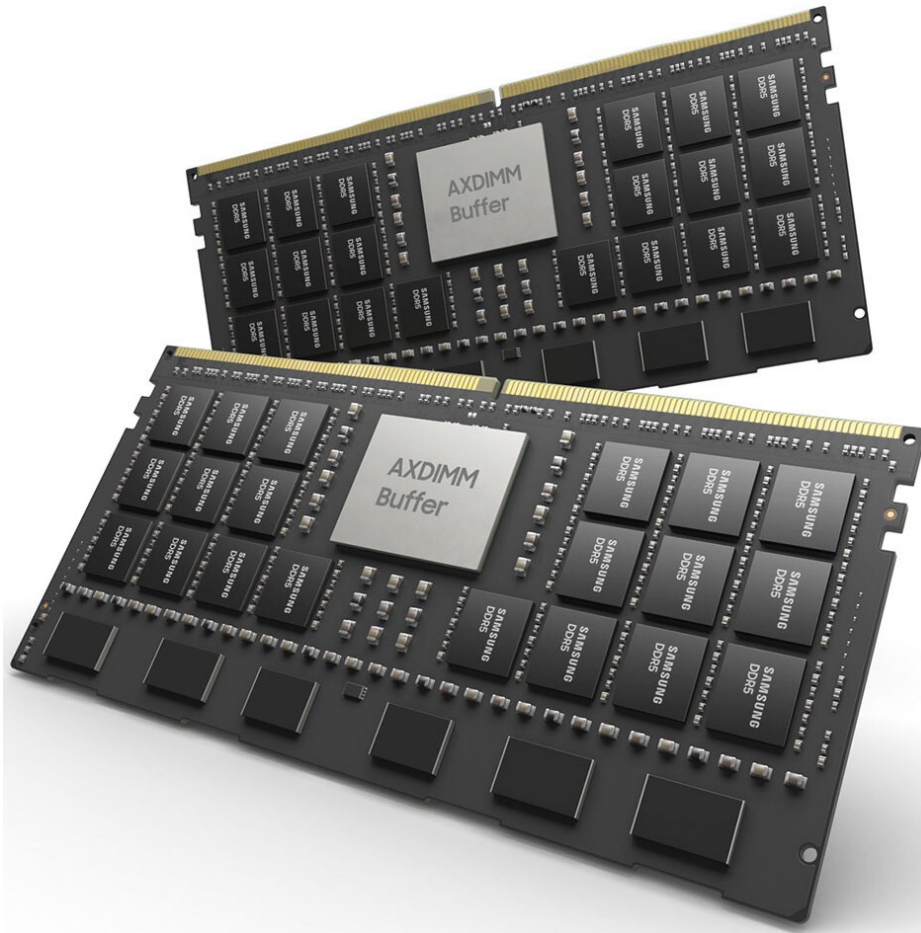
AiM: System Organization

■ GDDR6-based AiM architecture

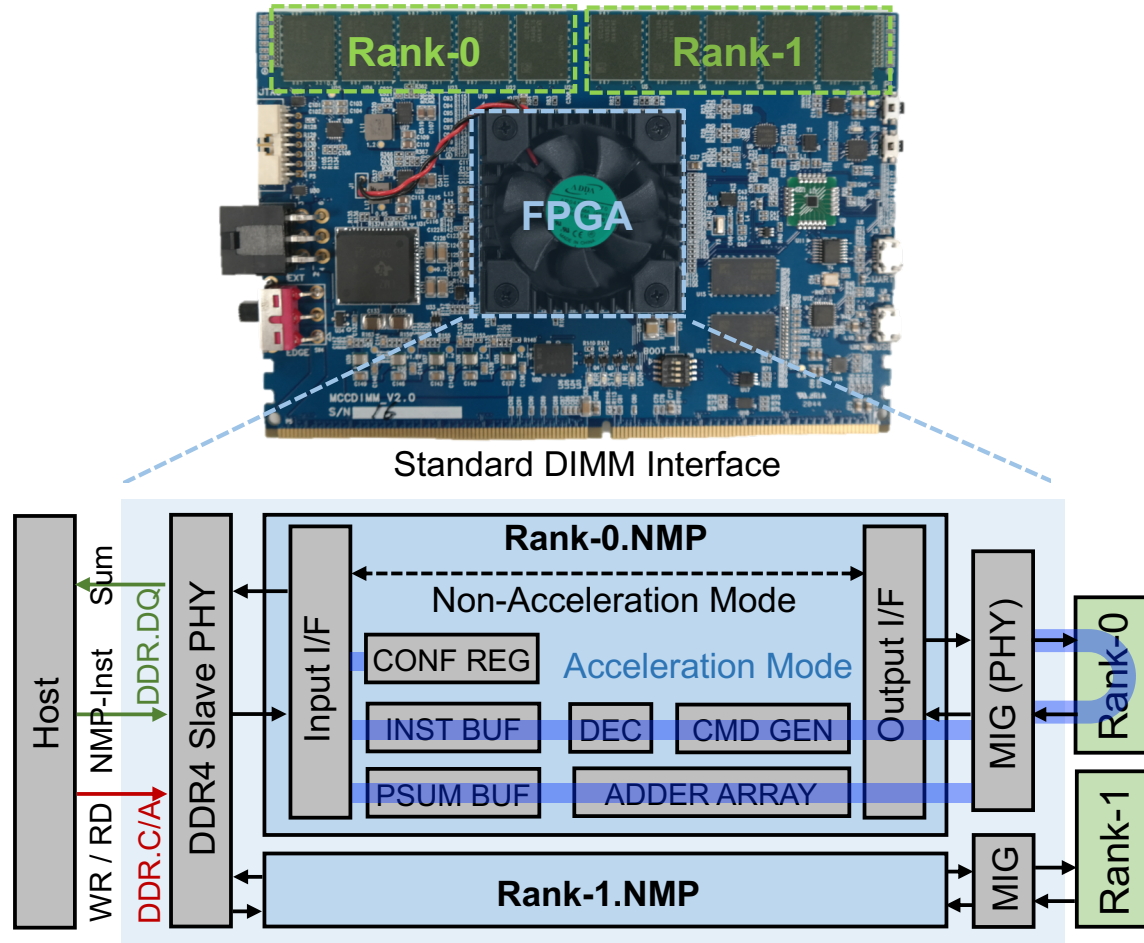


Samsung AxDIMM (2021)

- DIMM-based PIM
 - DLRM recommendation system



AxDIMM Design: Hardware Architecture



NMP-Inst
(64 bits)

OpCode	Locality	PSUM Tag	Trace End	Reserved	Row Addr	BG	BA	Col Addr
2 bit	1 bit	12 bit	1 bit	17 bit	17 bit	2 bit	2 bit	10 bit

Alibaba 3D Logic-to-DRAM Hybrid Bonding with Processing-near-Memory Engine

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29.1 184QPS/W 64Mb/mm² 3D Logic-to-DRAM Hybrid Bonding with Process-Near-Memory Engine for Recommendation System

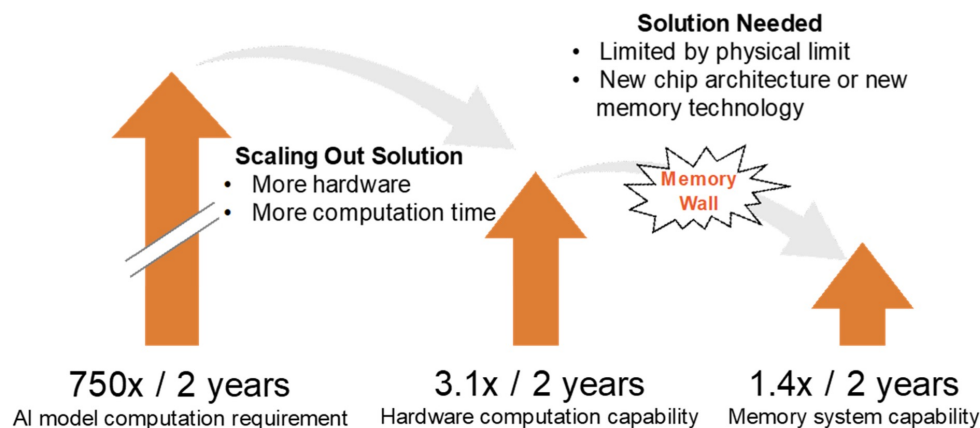
Dimin Niu¹, Shuangchen Li¹, Yuhao Wang¹, Wei Han¹, Zhe Zhang², Yijin Guan², Tianchan Guan³, Fei Sun¹, Fei Xue¹, Lide Duan¹, Yuanwei Fang¹, Hongzhong Zheng¹, Xiping Jiang⁴, Song Wang⁴, Fengguo Zuo⁴, Yubing Wang⁴, Bing Yu⁴, Qiwei Ren⁴, Yuan Xie¹

¹Alibaba DAMO Academy, Sunnyvale, CA; ²Alibaba DAMO Academy, Beijing, China

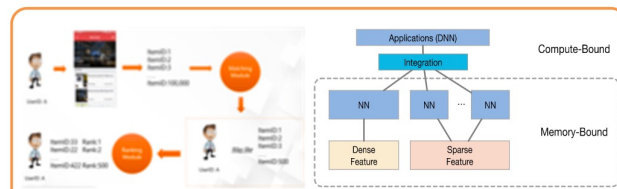
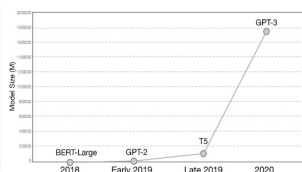
³Alibaba DAMO Academy, Shanghai, China; ⁴UnilC, Xian, China

Processing-in-Memory for Machine Learning

- Memory bandwidth is not enough for many ML workloads



Natural Language Processing



Recommendation Systems

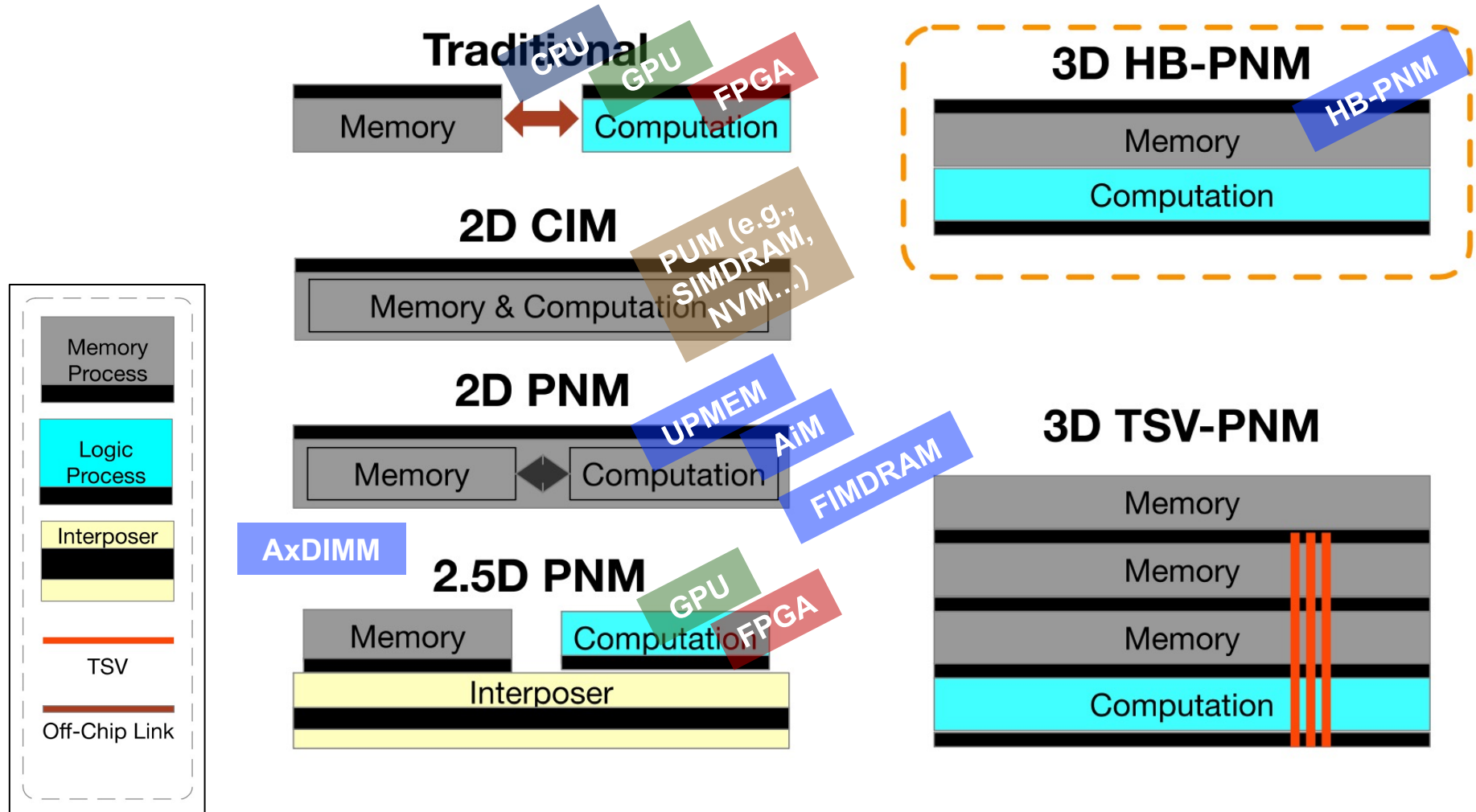


Graph Neural Network



Multi-Task Online Inference

Processing-in-Memory Classification



PNM : Process Near Memory
CIM: Compute In Memory

HB : Hybrid Bonding
TSV: Through-silicon Via

Two PIM Approaches

5.2. Two Approaches: Processing Using Memory (PUM) vs. Processing Near Memory (PNM)

Many recent works take advantage of the memory technology innovations that we discuss in Section 5.1 to enable and implement PIM. We find that these works generally take one of two approaches, which are categorized in Table 1: (1) *processing using memory* or (2) *processing near memory*. We briefly describe each approach here. Sections 6 and 7 will provide example approaches and more detail for both.

Table 1: Summary of enabling technologies for the two approaches to PIM used by recent works. Adapted from [309].

Approach	Enabling Technologies
Processing Using Memory	SRAM
	DRAM
	Phase-change memory (PCM)
	Magnetic RAM (MRAM)
Processing Near Memory	Resistive RAM (RRAM)/memristors
	Logic layers in 3D-stacked memory
	Silicon interposers
	Logic in memory controllers

Processing using memory (PUM) exploits the existing memory architecture and the operational principles of the memory circuitry to enable operations within main memory with minimal changes. PUM makes use

Onur Mutlu, Saugata Ghose, Juan Gomez-Luna, and Rachata Ausavarungnirun,
["A Modern Primer on Processing in Memory"](#)

*Invited Book Chapter in **Emerging Computing: From Devices to Systems - Looking Beyond Moore and Von Neumann**, Springer, to be published in 2021.*
[\[Tutorial Video on "Memory-Centric Computing Systems"](#) (1 hour 51 minutes)]

PIM Review and Open Problems

A Modern Primer on Processing in Memory

Onur Mutlu^{a,b}, Saugata Ghose^{b,c}, Juan Gómez-Luna^a, Rachata Ausavarungnirun^d

SAFARI Research Group

^a*ETH Zürich*

^b*Carnegie Mellon University*

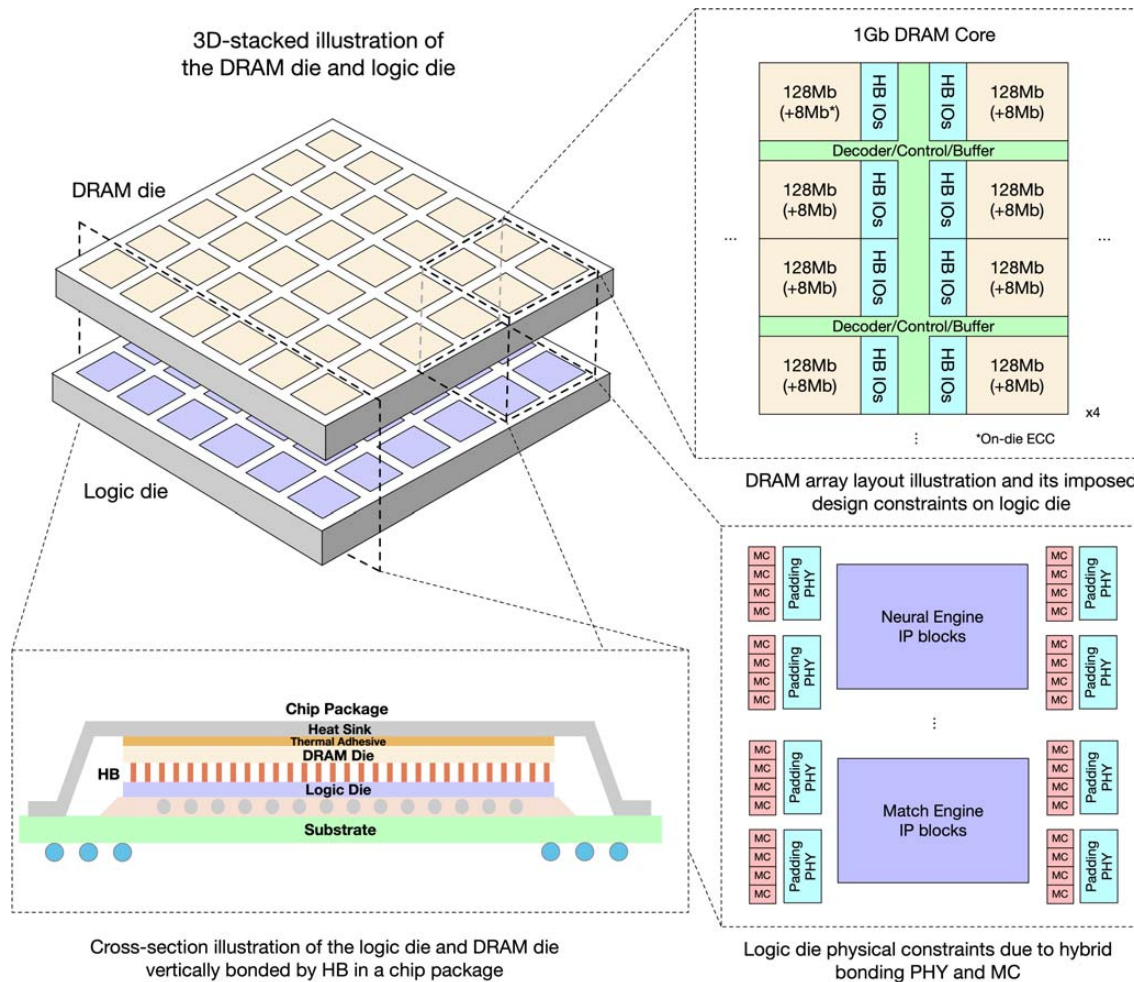
^c*University of Illinois at Urbana-Champaign*

^d*King Mongkut's University of Technology North Bangkok*

Onur Mutlu, Saugata Ghose, Juan Gomez-Luna, and Rachata Ausavarungnirun,
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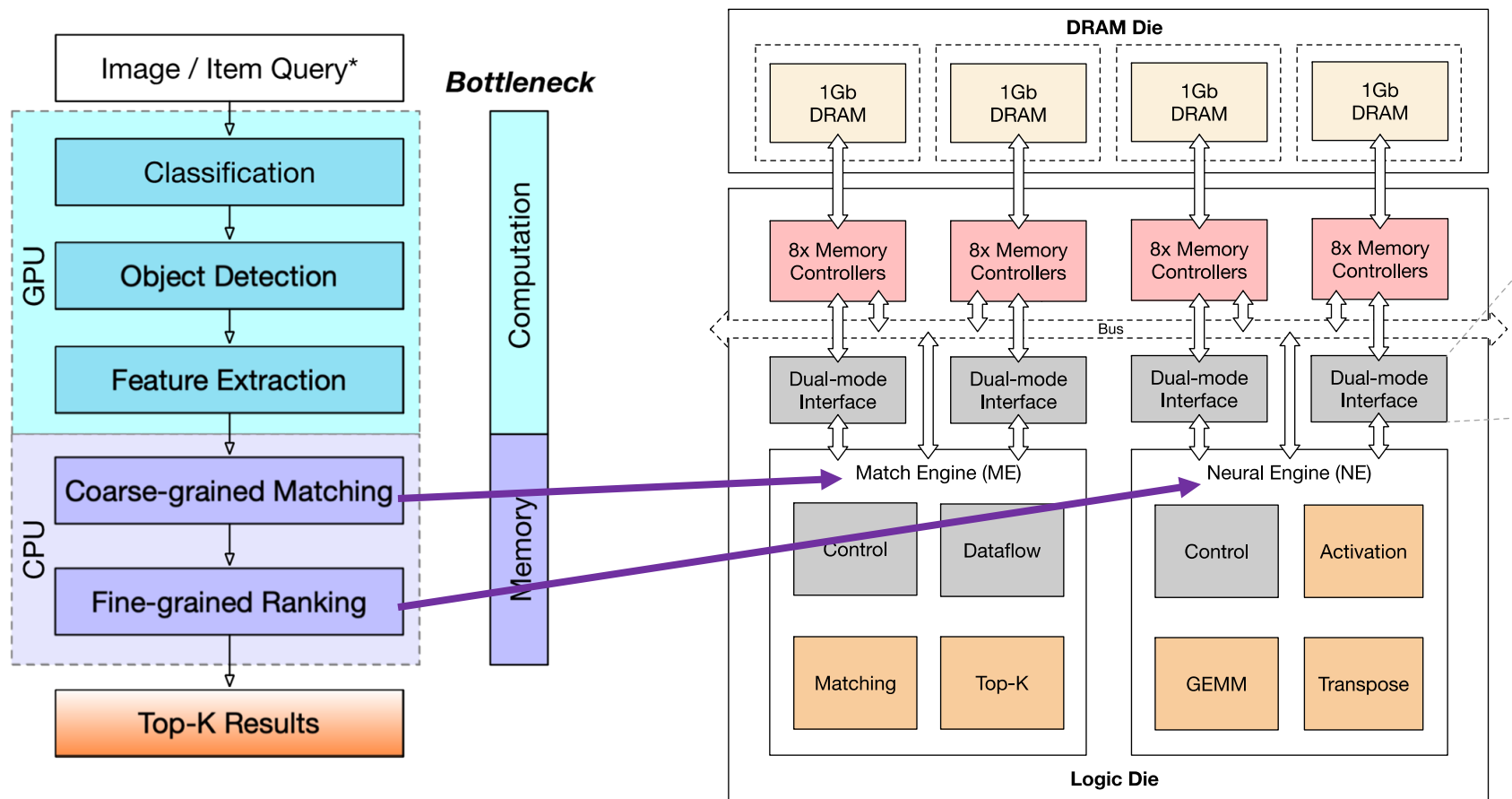
HB-PNM: Overall Architecture (I)

- 3D-stacked logic die and DRAM die vertically bonded by hybrid bonding (HB)



HB-PNM: Overall Architecture (II)

- Match engine and neural engine for matching and ranking in a recommendation system



Recommendation Systems

Feature Generation + Matching & Ranking

■ Recommendation system

□ Feature generation

- Classification, object detection, feature extraction

■ Compute-bound

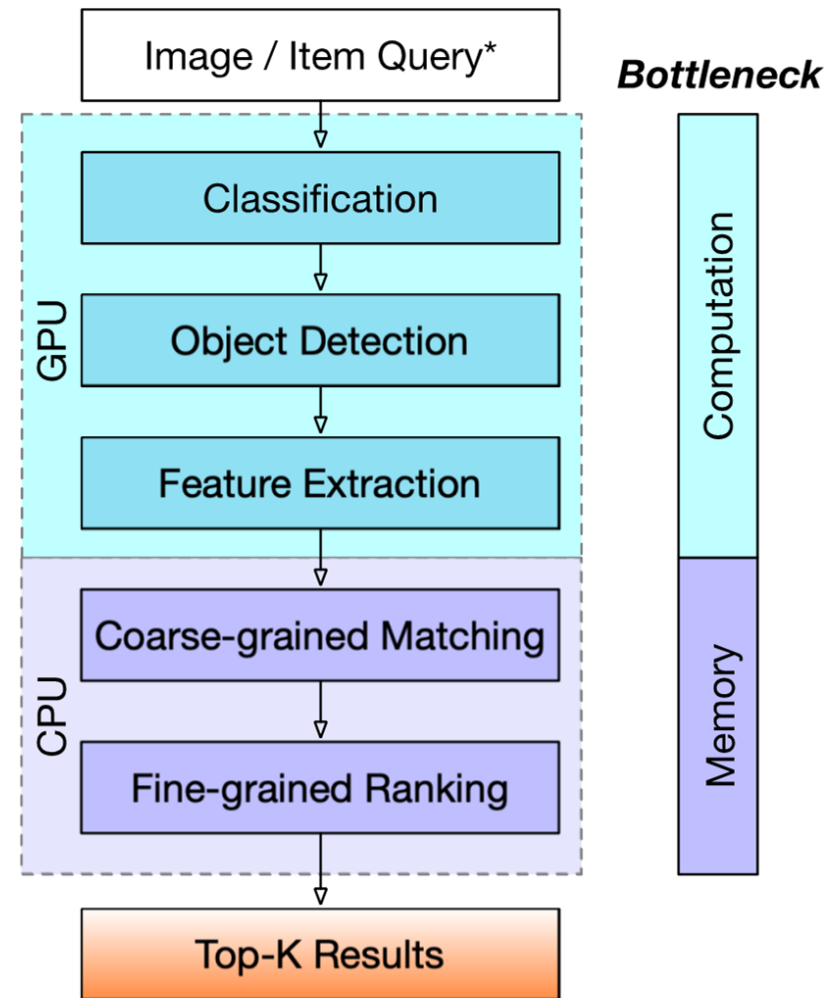
- Good fit for GPU

□ Matching and ranking

- Coarse-grained matching, fine-grained ranking

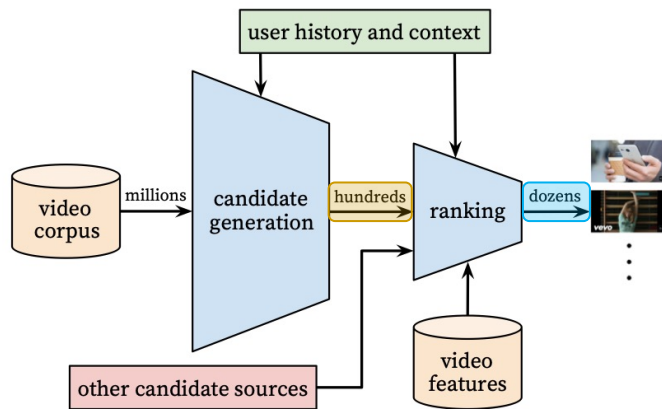
■ Memory-bound

- Most latency (89.87%) and energy (82.97%)
- Typically run on CPU

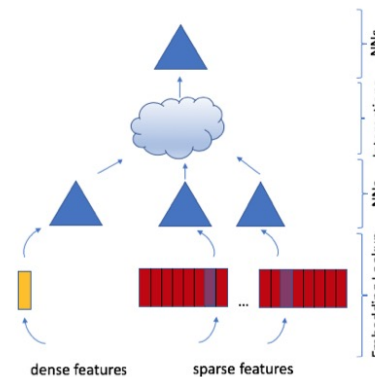


Recommendation Systems

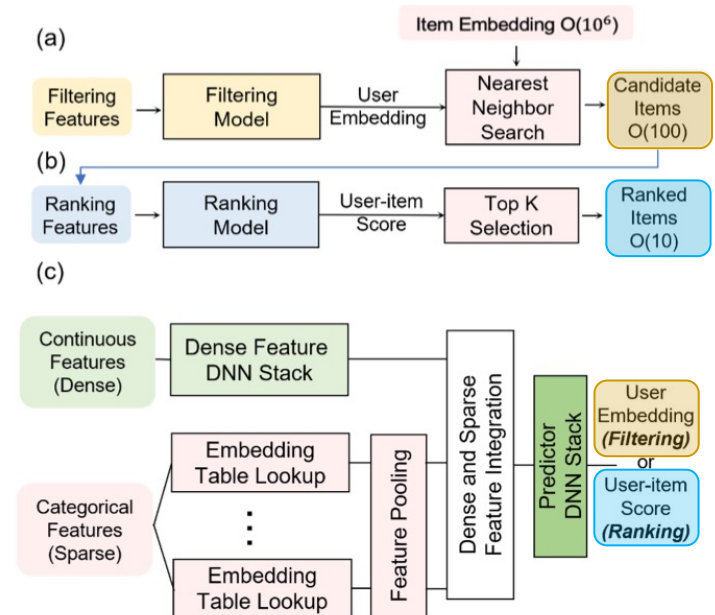
- Candidate recommendations are **retrieved** and then **ranked**



Covington et al., Deep Neural Networks for YouTube Recommendations, RecSys 2016



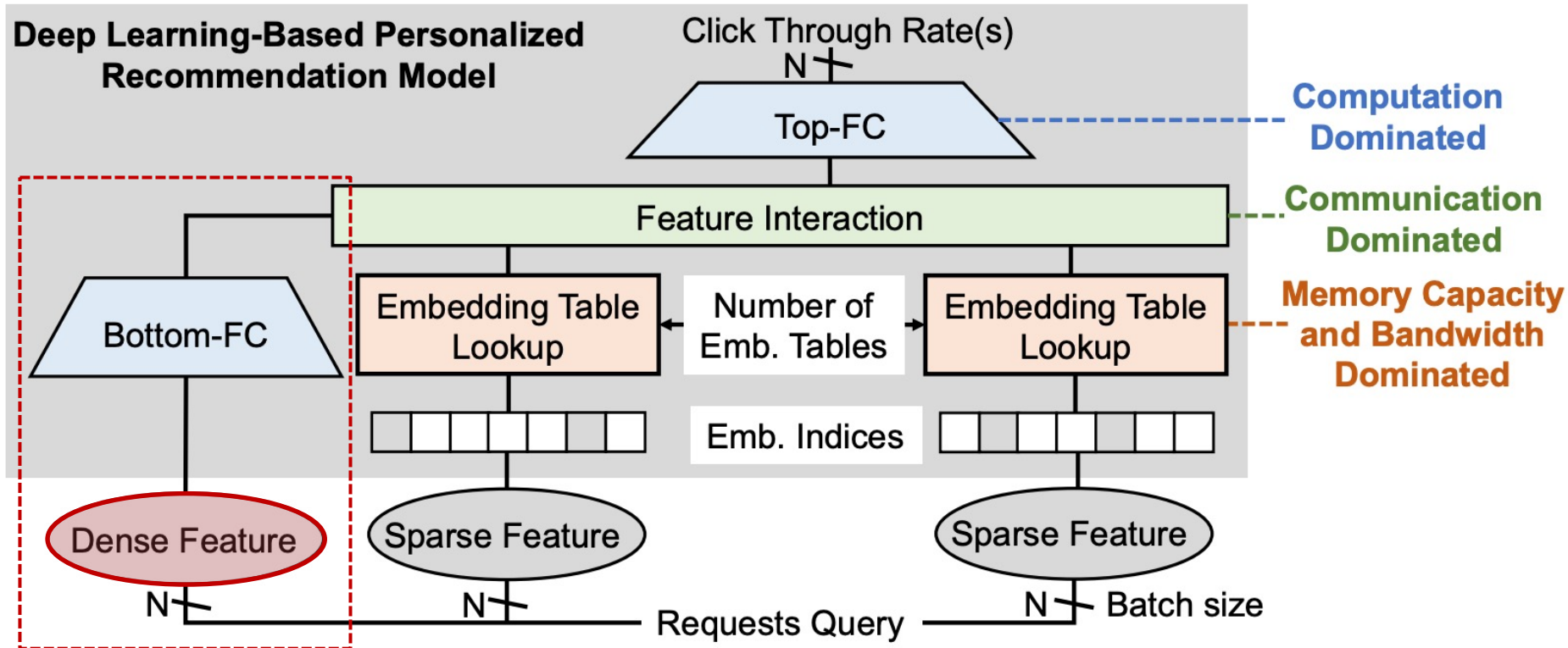
Naumov et al., Deep Learning Recommendation Model for Personalization and Recommendation Systems, arXiv:1906.00091, 2019



Li et al., iMARS: An In-Memory-Computing Architecture for Recommendation Systems, arXiv:2202.09433, 2022

Overview of Recommendation Models

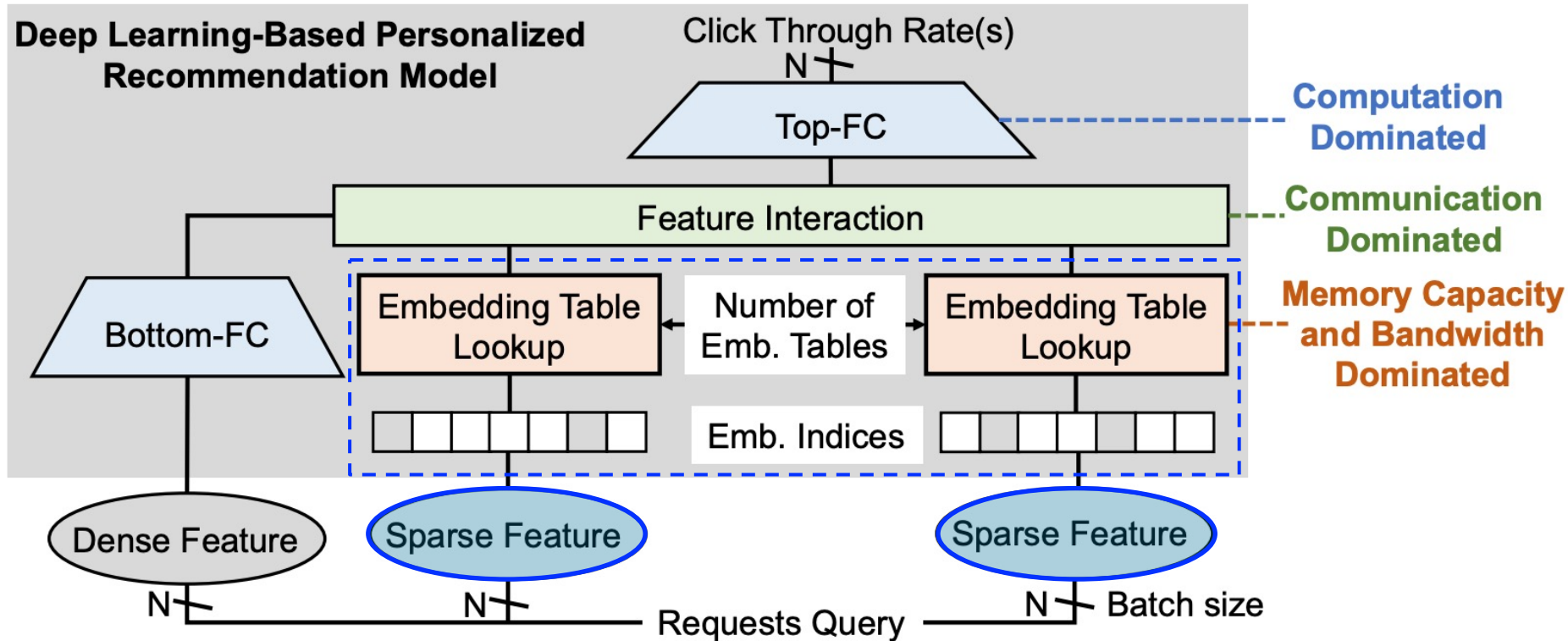
- **Personalized recommendation**: recommend content to users, e.g., Facebook's DLRM recommendation system



Dense features: continuous inputs in vectors and matrices are processed by typical DNN layers (e.g., fully connected layers)

Overview of Recommendation Models

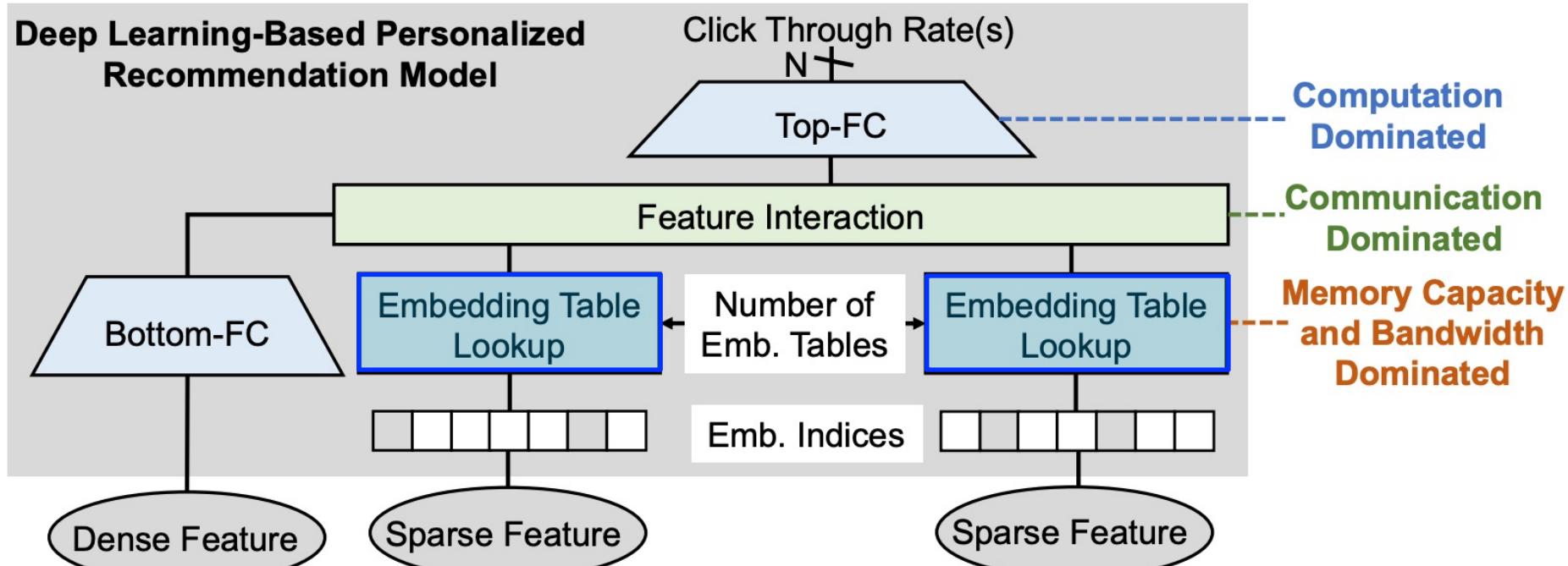
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Sparse features: for categorical inputs;
processed by indexing large embedding tables

Overview of Recommendation Models

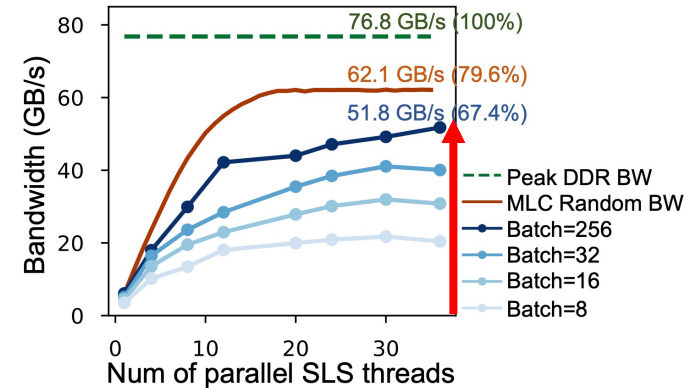
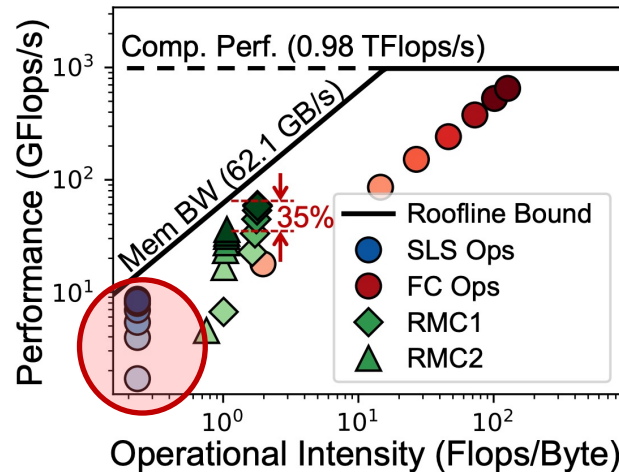
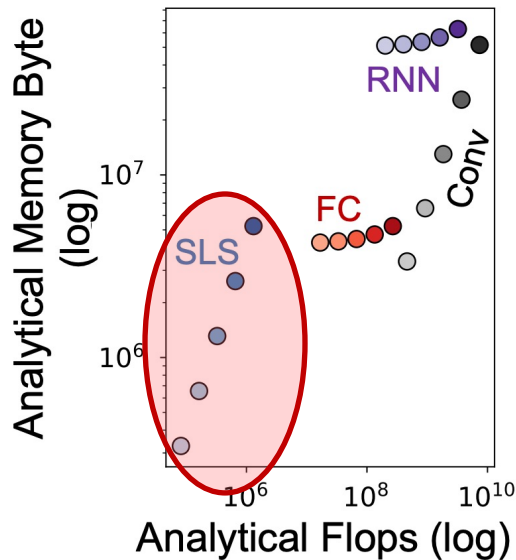
- **Personalized recommendation**: recommend content to users, e.g., Facebook's DLRM recommendation system



Embedding tables are organized as a set of potentially millions of vectors: lookup and pooling operations represent sparse features learned during training and generally exhibit **Gather-Reduce pattern**, via Caffe2's **SparseLengths (SLS) operators**

DLRM Performance Characterization

- Identifying **key performance bottlenecks** for the DLRM system



SparseLengths (SLS) operators:

- **Low FP intensity**
- Larger batch size:
 - Higher memory footprint
 - Higher memory intensity

The **memory bandwidth can easily be saturated** by embedding operations especially as both the batch size and the number of threads increase

Feature Generation + Matching & Ranking

■ Recommendation system

□ Feature generation

- Classification, object detection, feature extraction

■ Compute-bound

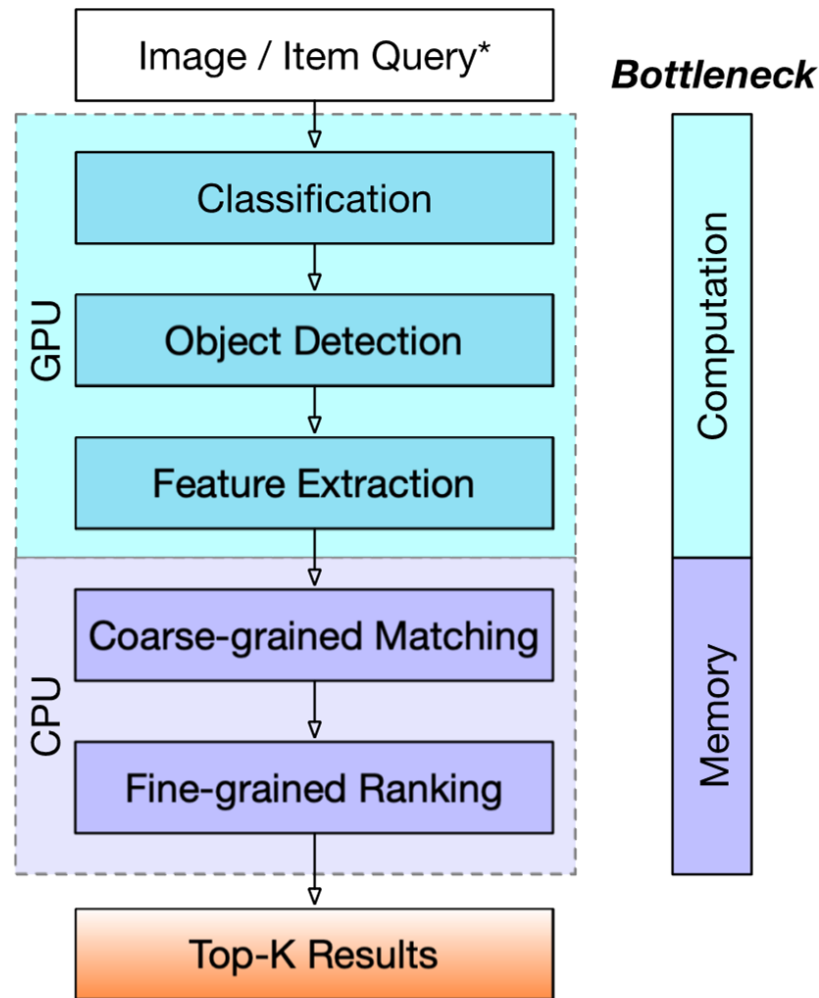
- Good fit for GPU

□ Matching and ranking

- Coarse-grained matching, fine-grained ranking

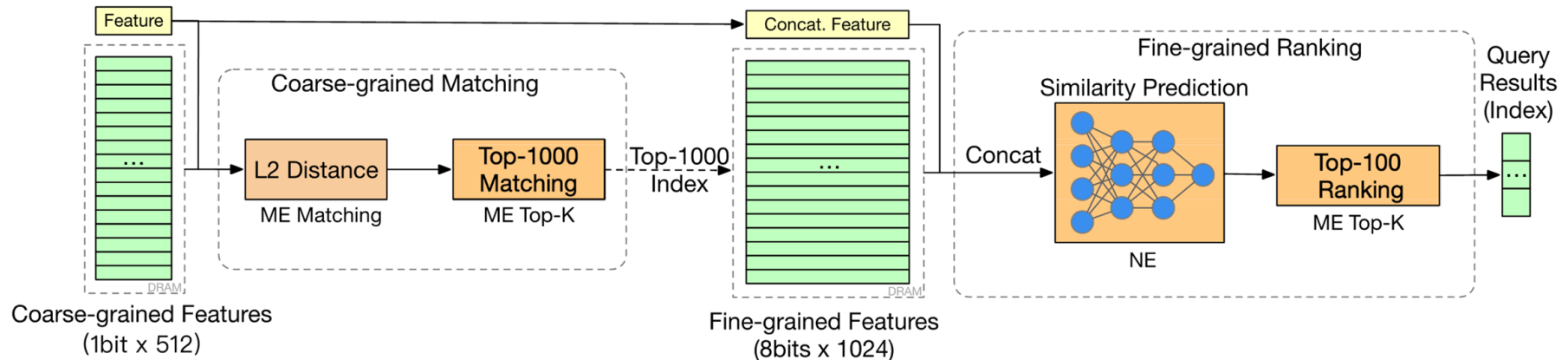
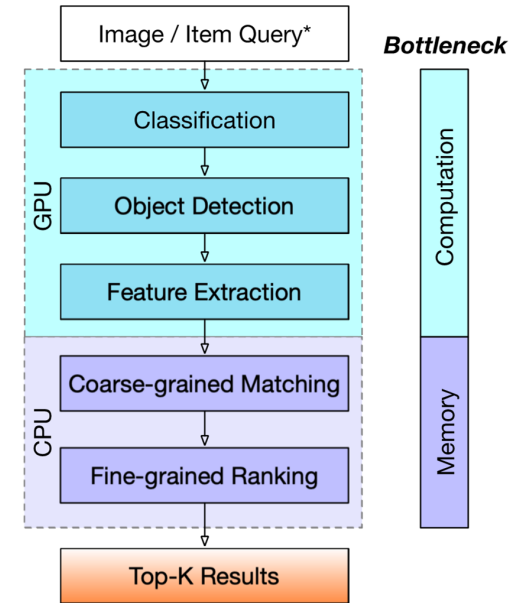
■ Memory-bound

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Matching & Ranking

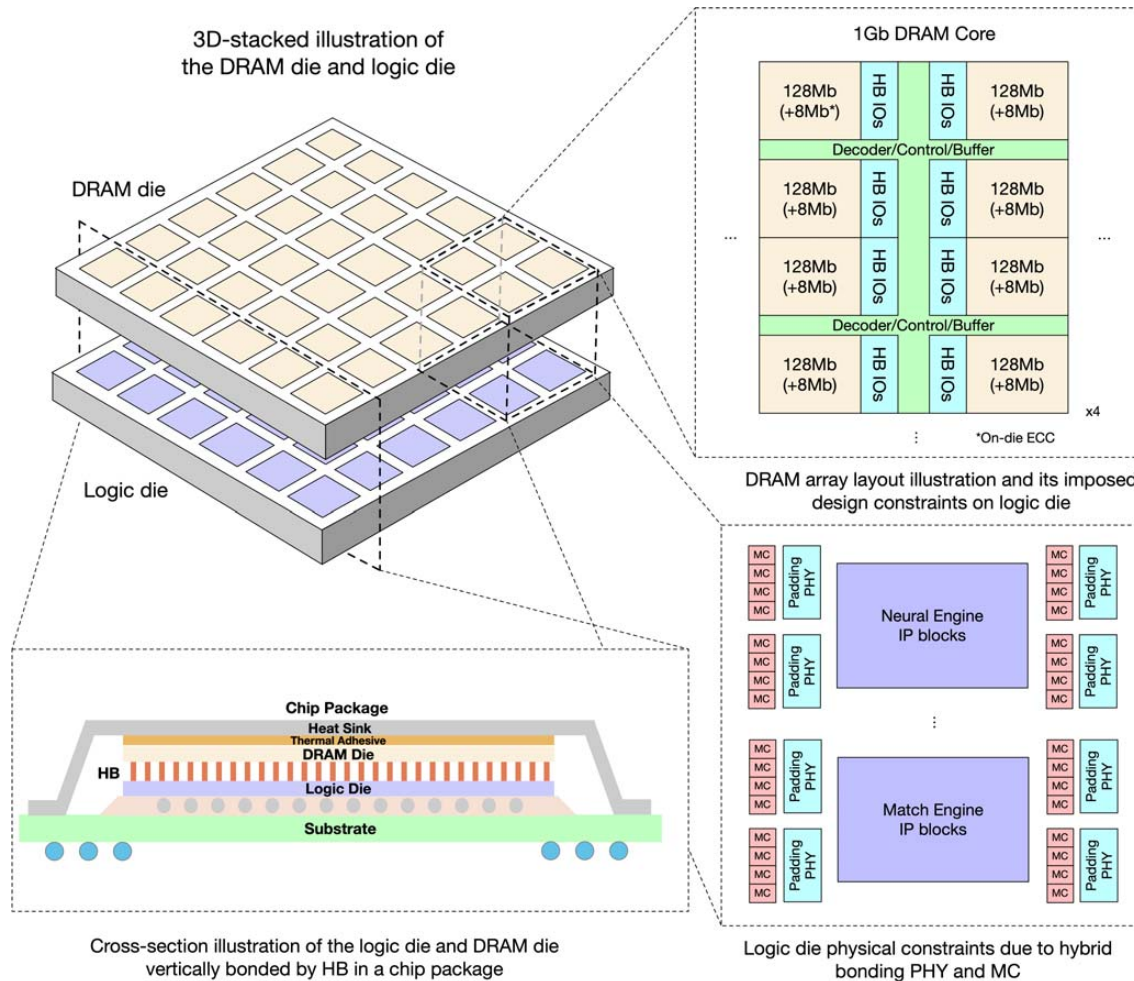
- Coarse-grained matching
 - ❑ Binary feature vectors with 512 dimensions
 - ❑ Distance calculation
 - ❑ Top-1000 items selected from 40K items
- Fine-grained ranking
 - ❑ Features with 8 bits x 1024 dimensions
 - ❑ 3-layer MLP (2048-256-64-1) for similarity prediction
 - ❑ Top-100 ranking results from 1K items



3D Logic-to-DRAM Hybrid Bonding

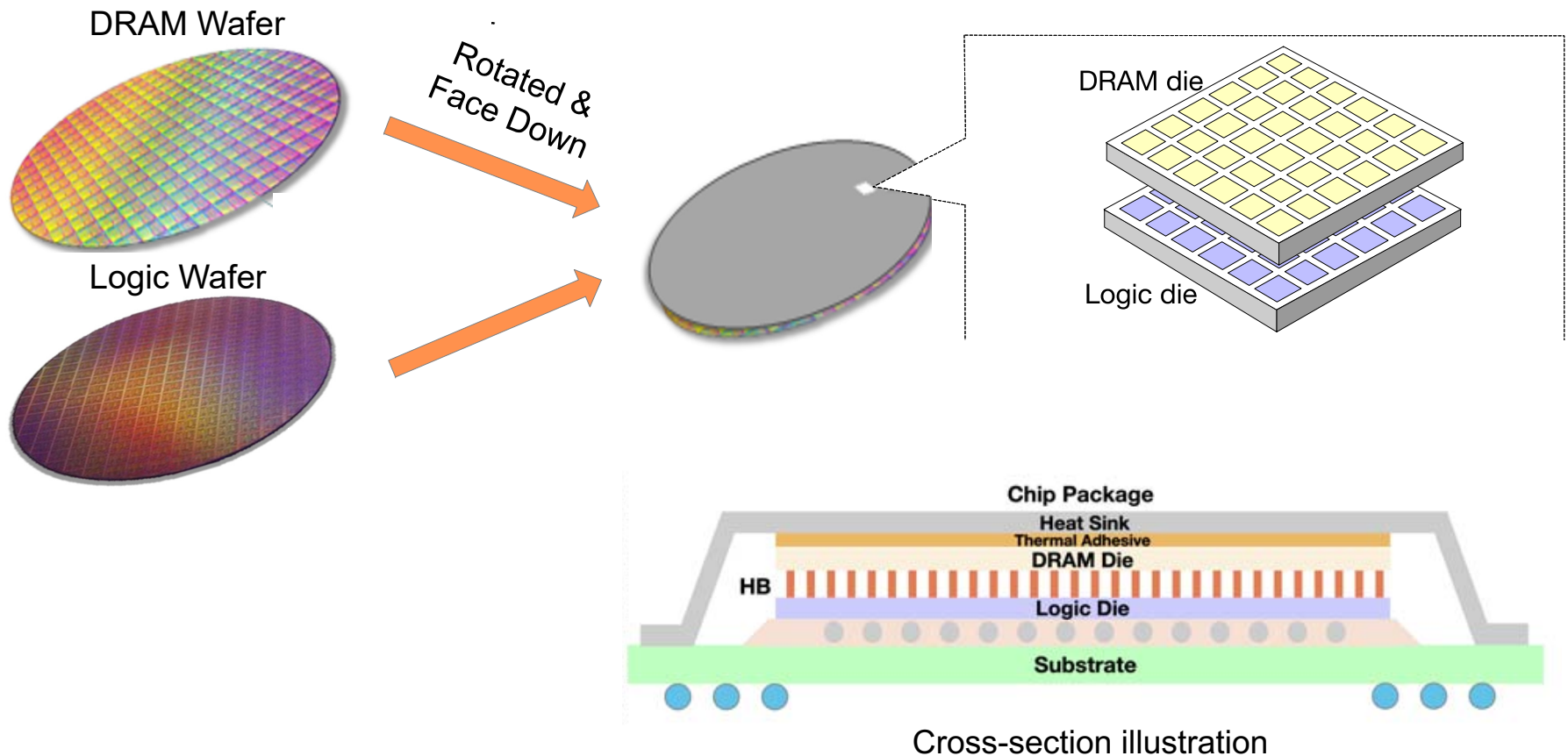
HB-PNM: Overall Architecture (I)

- 3D-stacked logic die and DRAM die vertically bonded by hybrid bonding (HB)



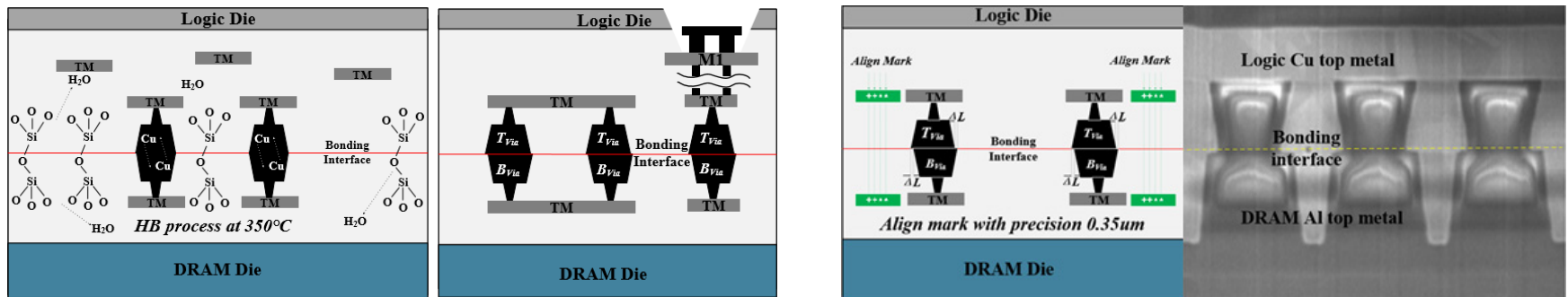
HB-PNM: Chip Implementation

- 3D Logic-to-DRAM Hybrid Bonding
 - Face-to-face hybrid wafer bonding



HB-PNM: Hybrid-Bonding Interconnection

- 3D Logic-to-DRAM Hybrid Bonding
 - Face-to-face hybrid wafer bonding
 - Logic and memory manufactured independently: this avoids the challenges of integrating logic into memory chips
 - Cu-Cu direct fusion with low bonding temperature ($<350^{\circ}\text{C}$)
 - Much denser vias than other 3D-stacking technologies
 - Low pitch size (3 μm) vs. HBM microbumps (35 μm^1)
 - High inter-layer bandwidth (1.38 TB/s) vs. HBM2E (460 GB/s²)

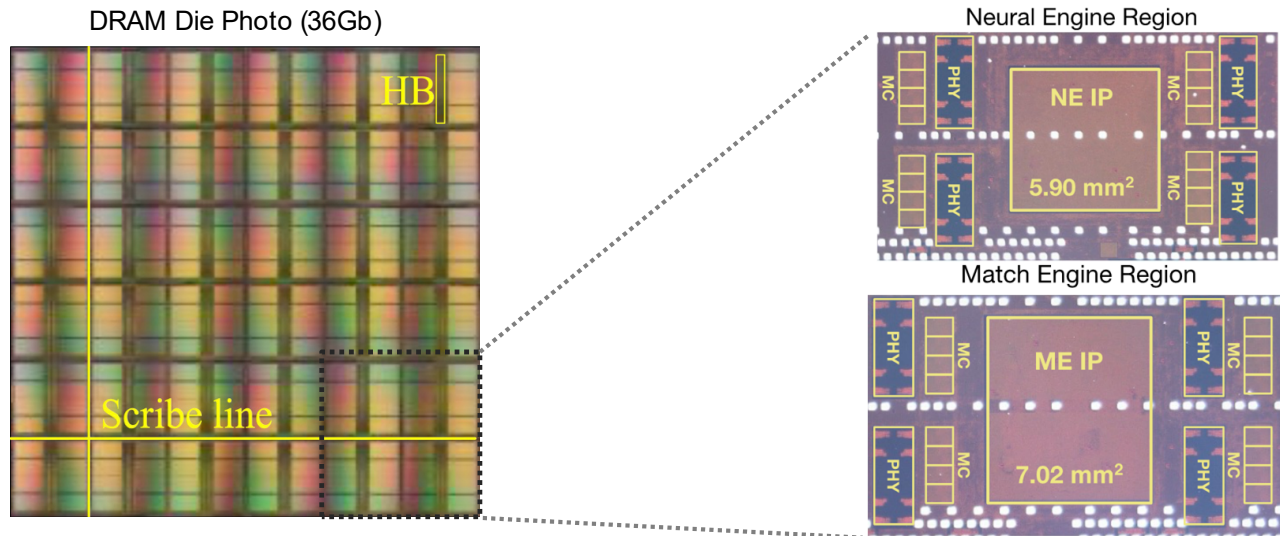


¹ Kim et al. Signal Integrity and Computing Performance Analysis of a Processing-In-Memory of High Bandwidth Memory (PIM-HBM) Scheme, IEEE TCPMT, 2021

² <https://product.skhynix.com/products/dram/hbm/hbm2e.go>

HB-PNM: DRAM Die and Logic Die

■ DRAM die and logic die



DRAM Die		
Technology	25nm	
Area	Total*	602.22 mm ²
	Neural Engine	32 mm ²
	Match Engine	32 mm ²
Voltage	1.1 V	
Frequency (max)	150 MHz	
Power	300 mW per 1Gb	
Bandwidth**	153.60 GB/s / 1.38 TB/s	

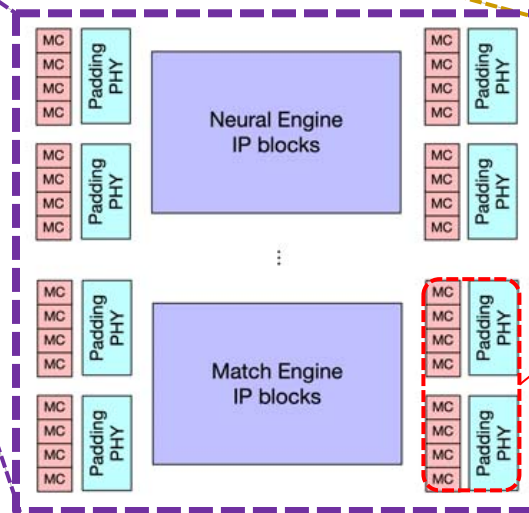
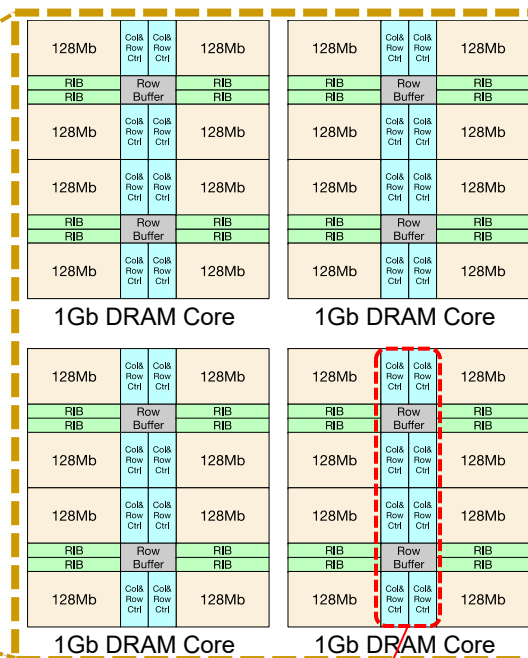
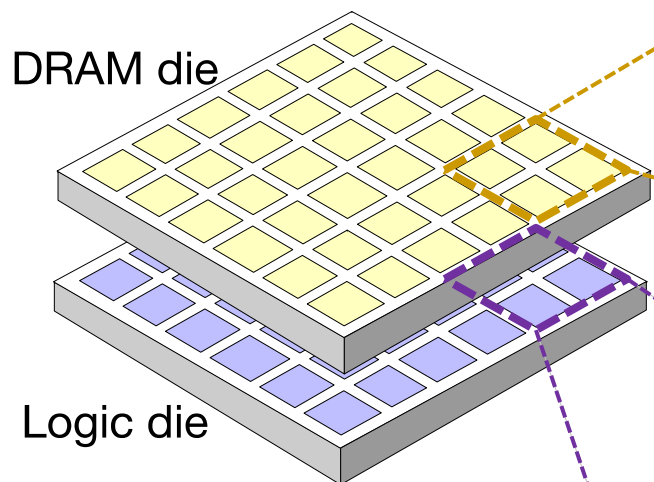
Logic Die		
Technology	55nm	
Area	Total*	602.22 mm ²
	Neural Engine	5.90 mm ²
	Match Engine	7.02 mm ²
# of MC	16 per IP	
Voltage	1.2 V	
Frequency	300 MHz	
Power	977.70 mW	
Precision	INT8	

HB-PNM Architecture

HB-PNM Architecture

- DRAM die composed of 6x6 1Gb DRAM cores

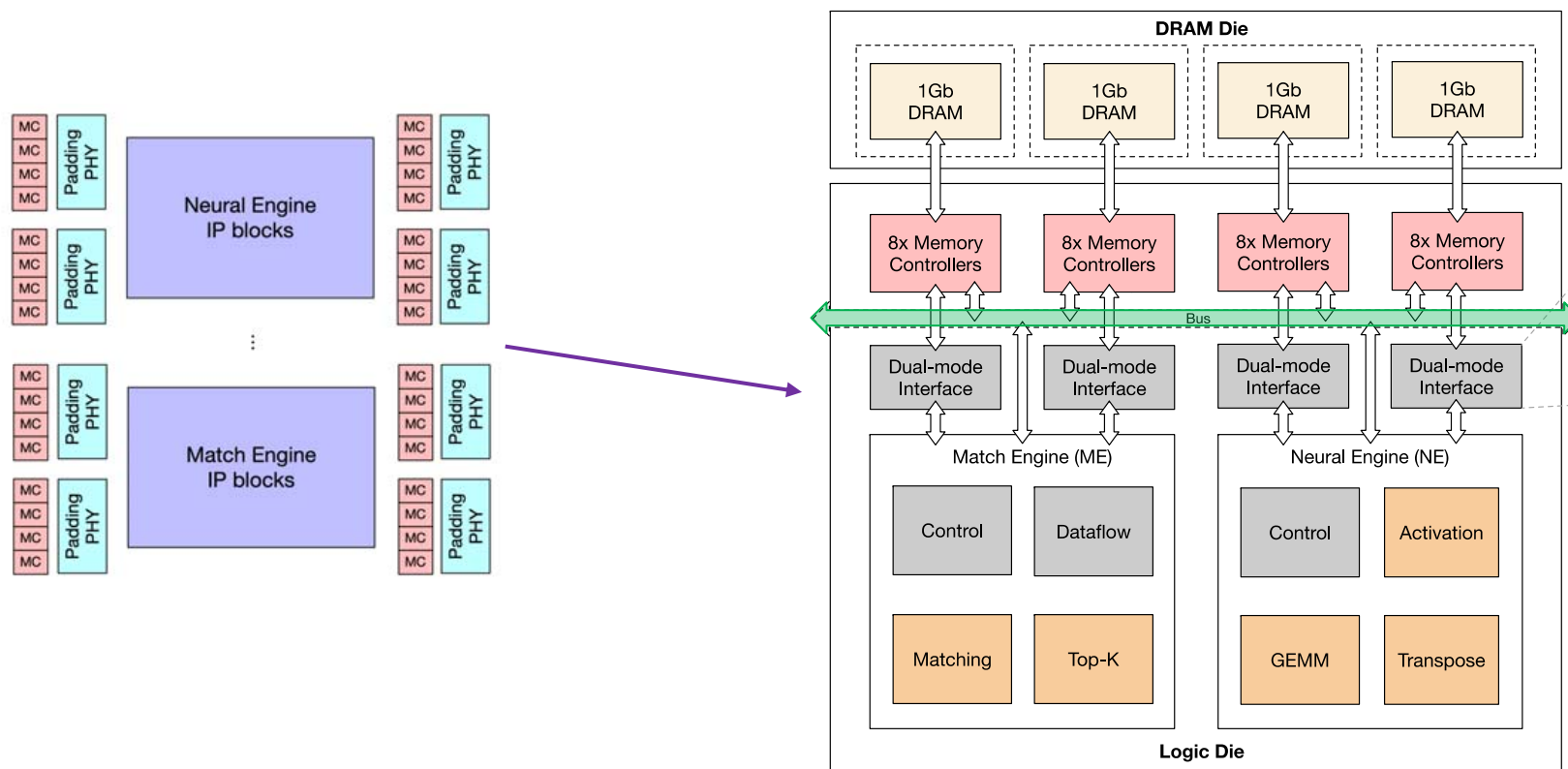
- ❑ 8 banks per core
- ❑ 128-bit I/O per bank
- ❑ On-chip ECC (8 Mb per 128 Mb)



HB imposes design constraints on location of memory controllers (MC) and PHY

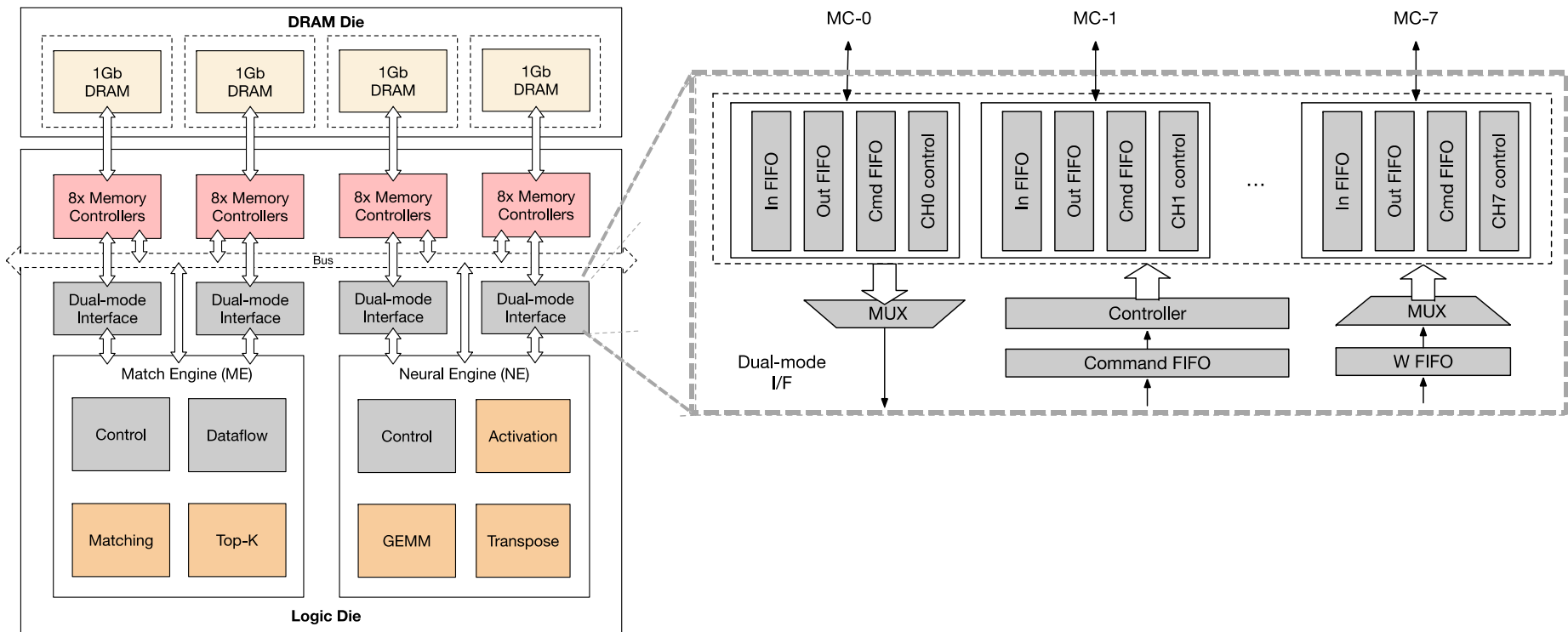
HB-PNM: Logic Die

- Match engine and neural engine for matching and ranking in a recommendation system
 - ❑ Direct access to their counterpart DRAM blocks
 - ❑ Access to other DRAM blocks via on-chip bus



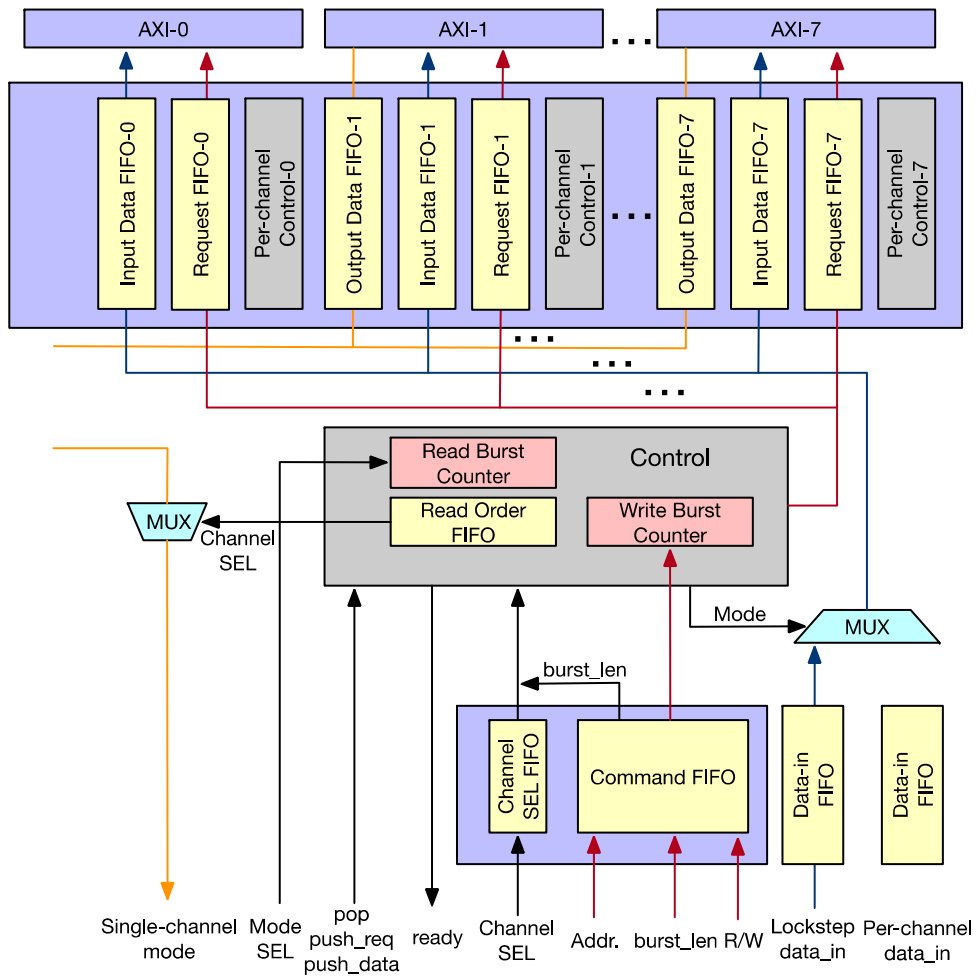
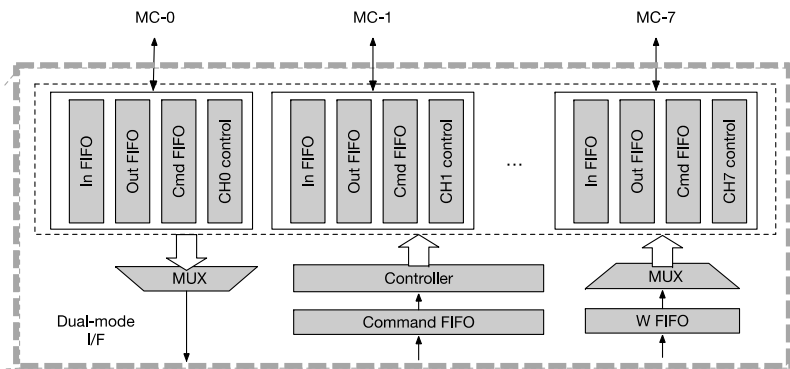
HB-PNM Logic Die: Dual-mode Interface

- **Dual-mode interface** can switch between
 - ❑ All 8 banks in lock-step for full bandwidth
 - ❑ Single channel (1 of 8 banks)



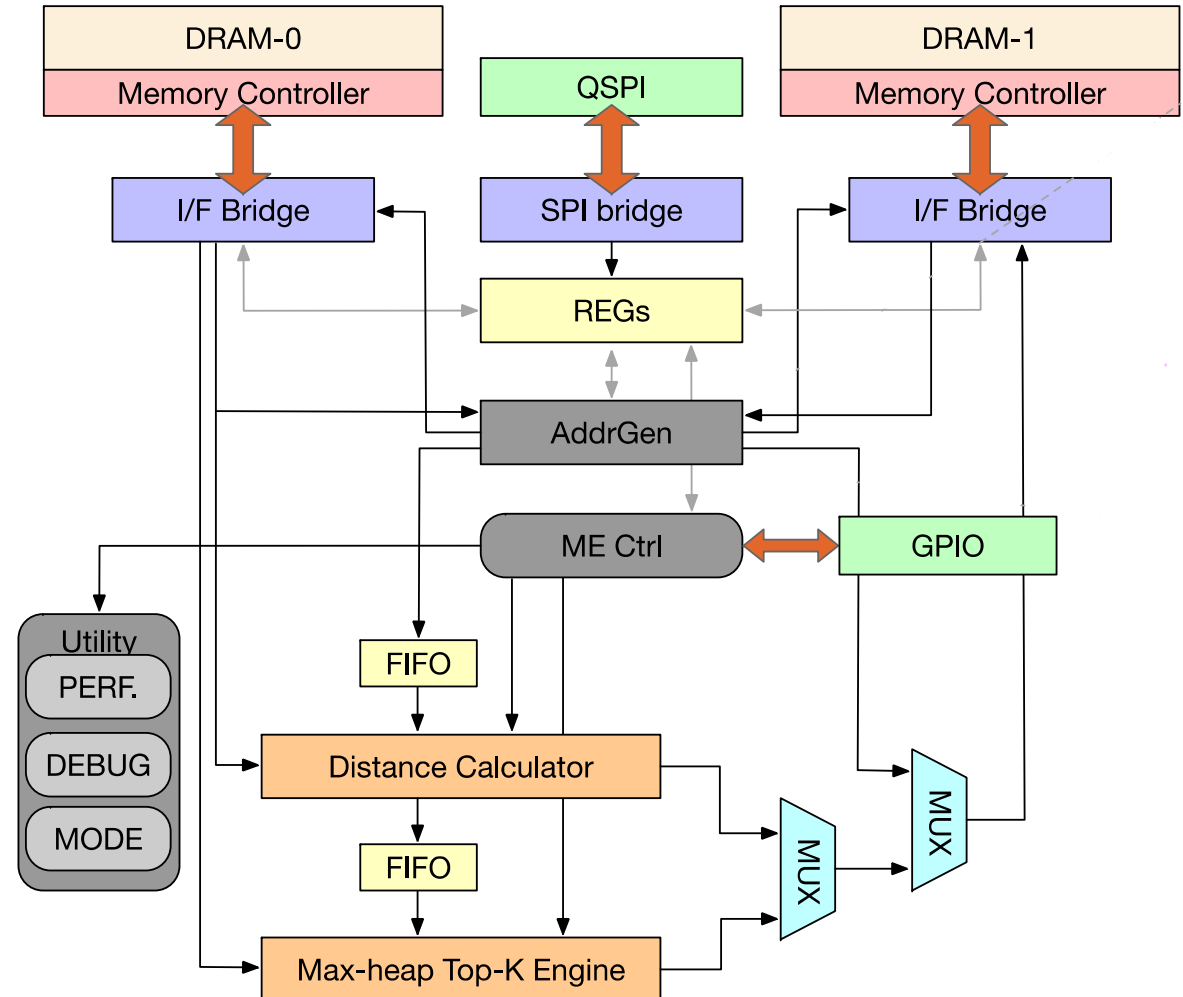
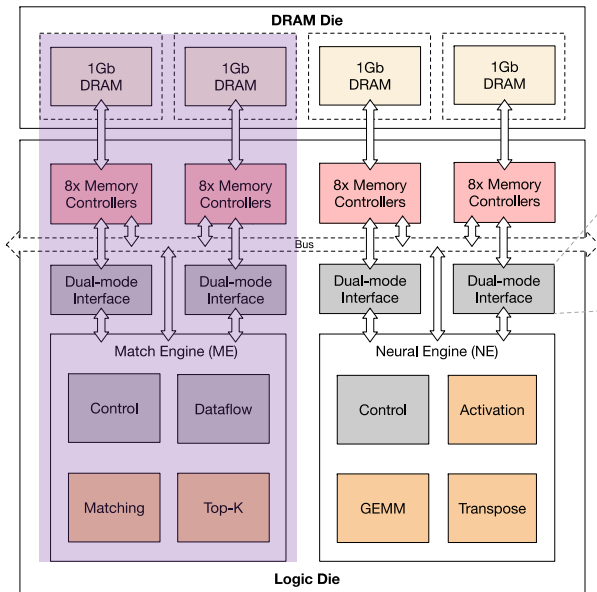
Neural Engine: Interface Bridge

- Support for single-channel mode and lockstep mode
- **Read/write counters** to support burst requests



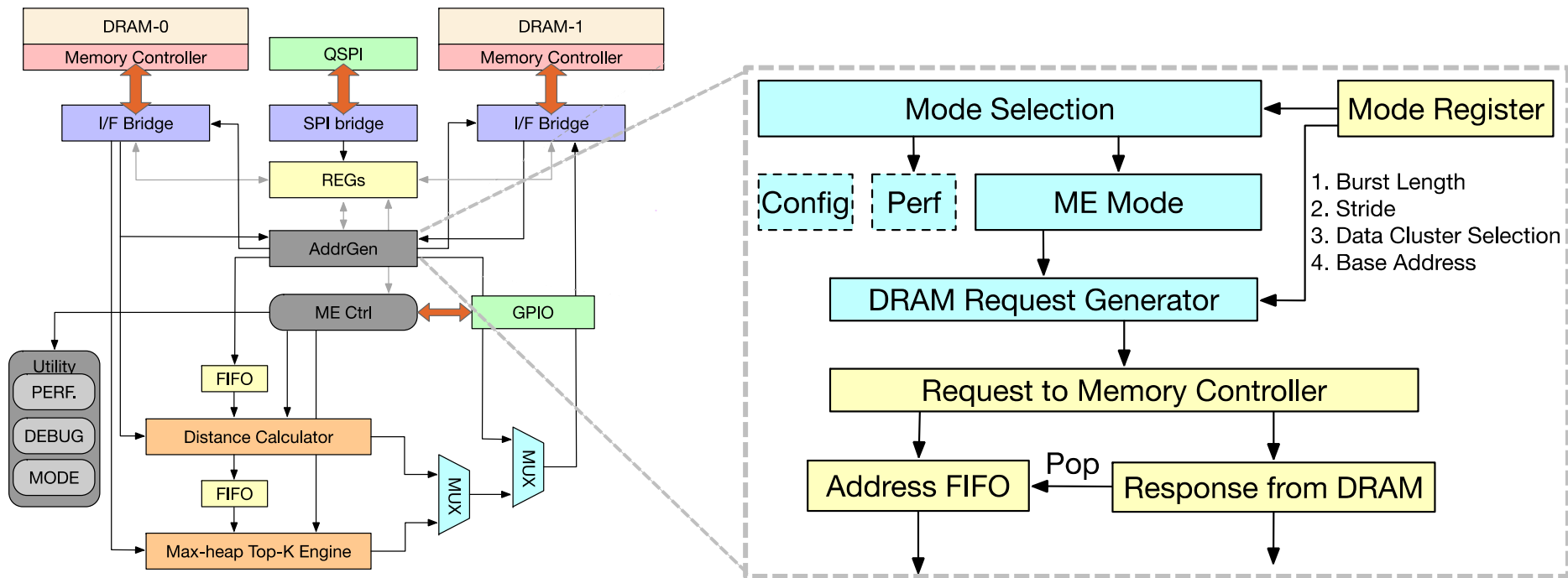
HB-PNM: Match Engine

- Responsible for coarse-grained matching



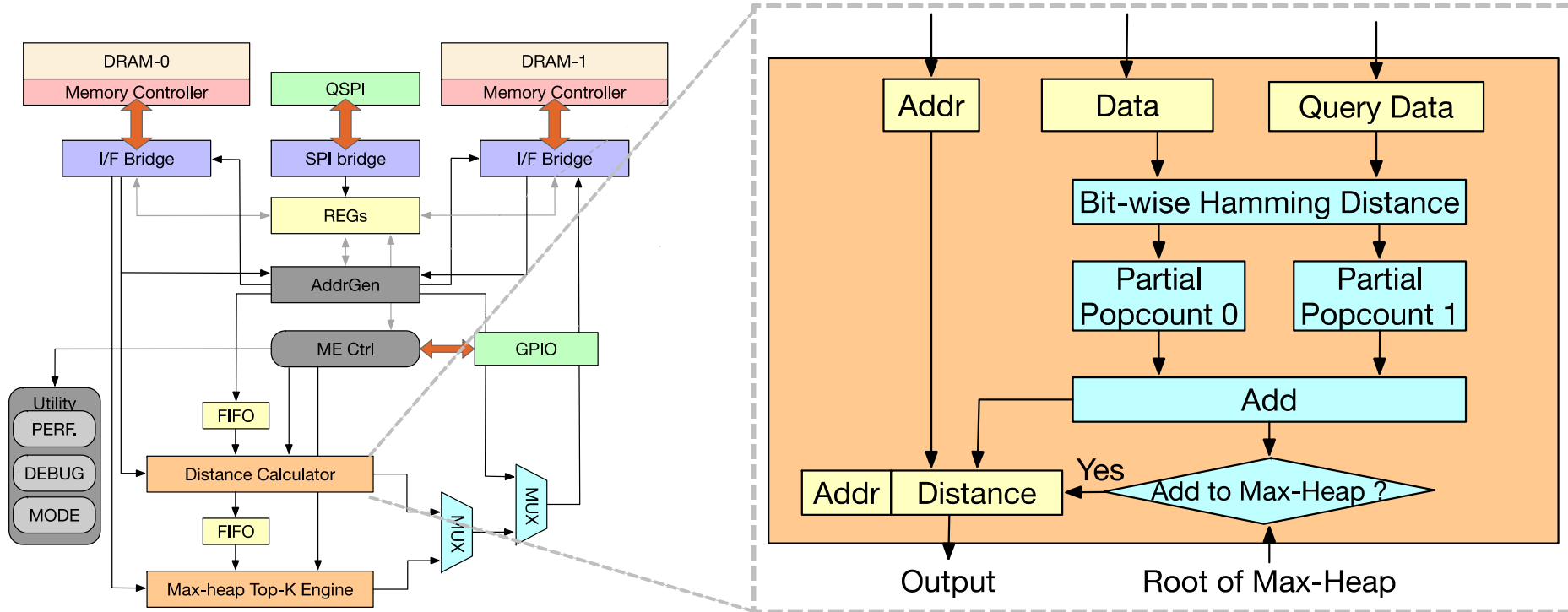
Match Engine: Address Generator

- **AddGen** generates the address of the input query
 - ❑ Mode selection for **different access patterns**
 - ❑ Configurable via registers



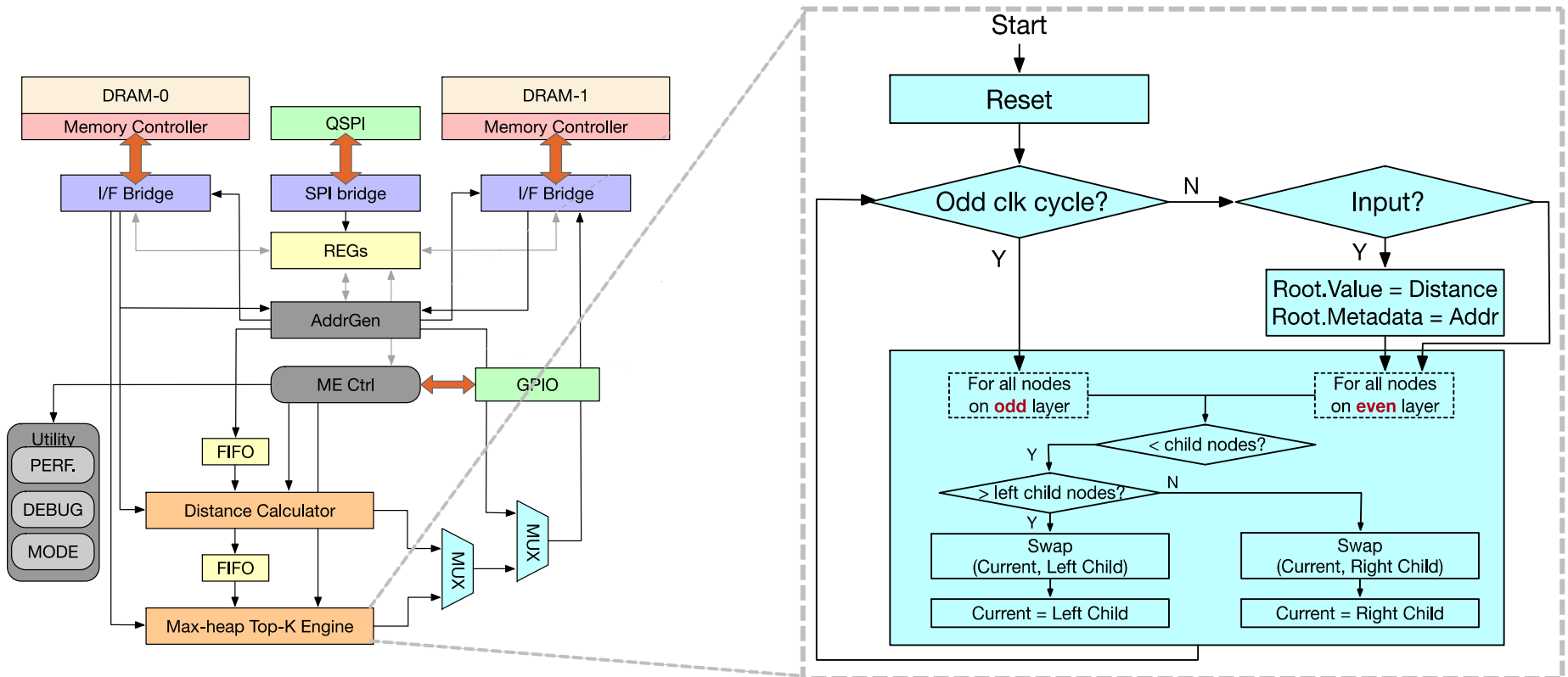
Match Engine: Distance Calculator

- **Distance calculator** obtains similarity between input query and feature vectors
 - It computes **Hamming distance of two 512-bit vectors**
 - Distance is filtered by root of max-heap



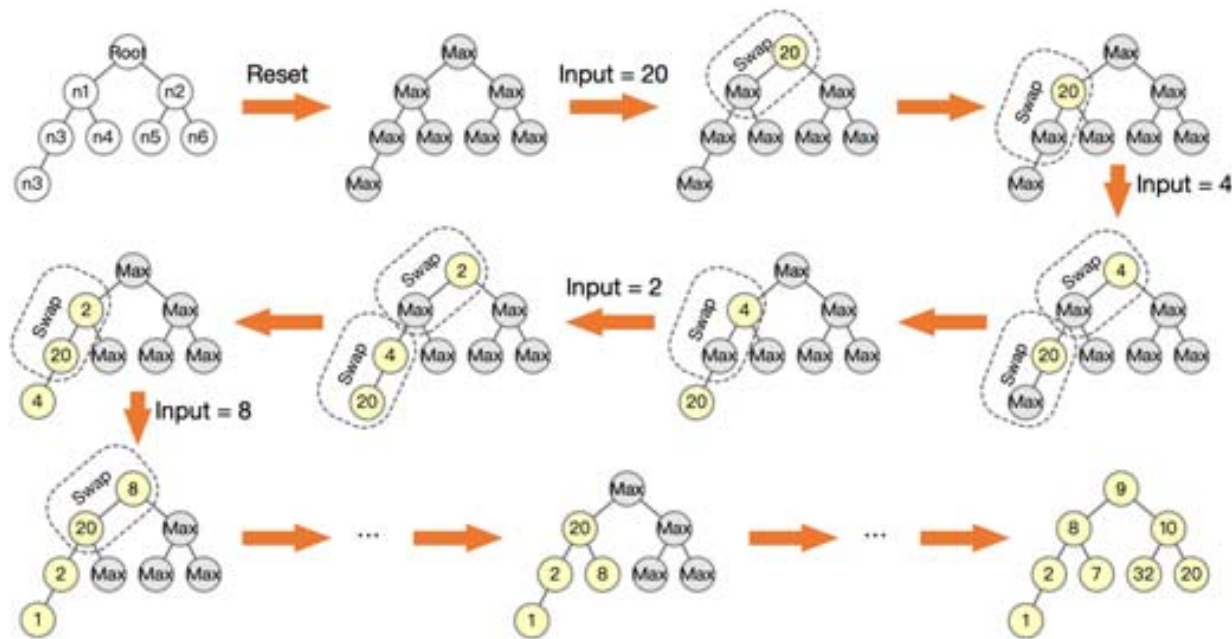
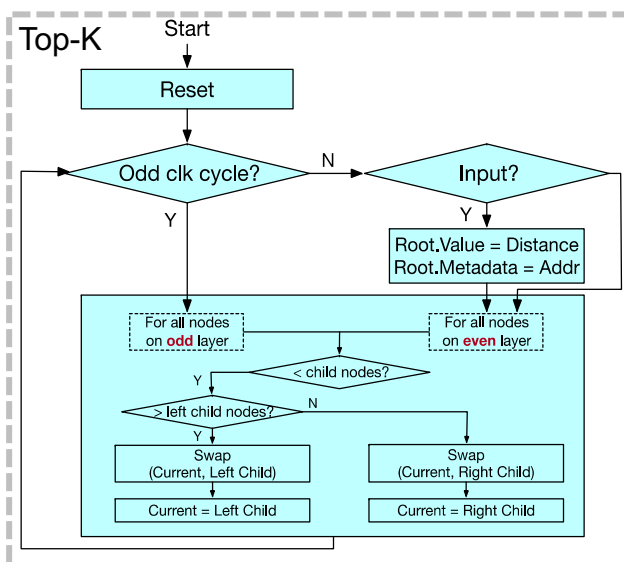
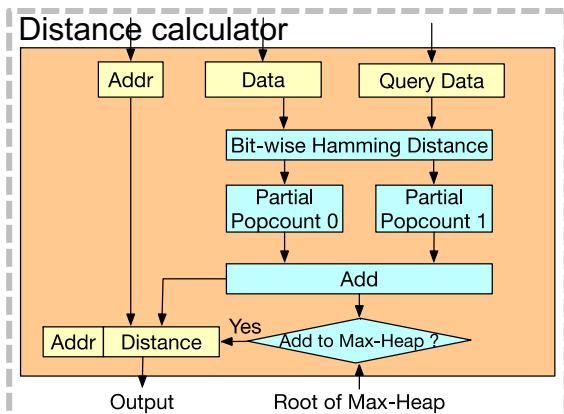
Match Engine: Top-K Engine (I)

- Max-heap hardware block and data structure with 1000 nodes
<address, distance> for the 1000 shortest distances
 - New input every two cycles



Match Engine: Top-K Engine (II)

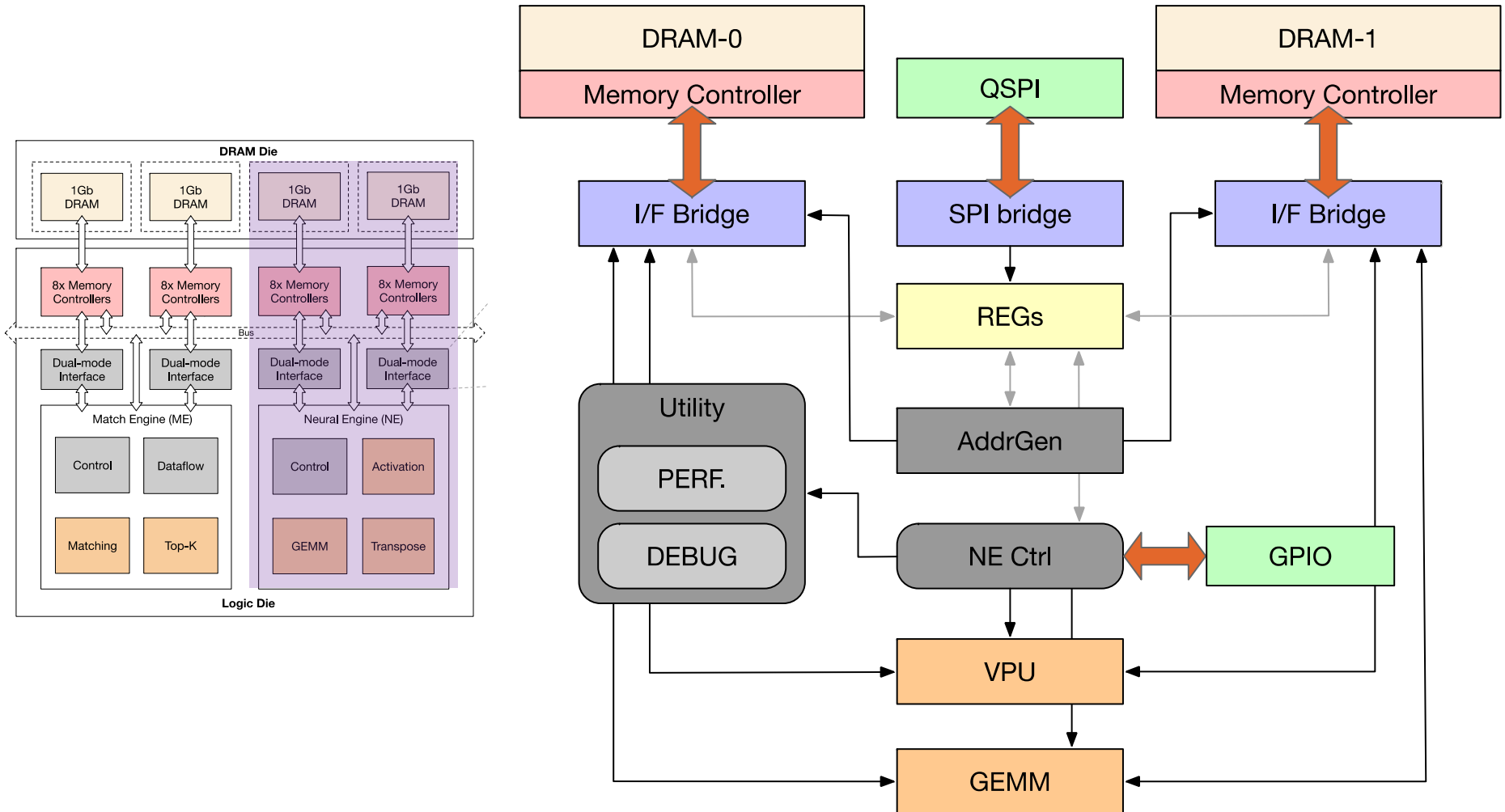
- Max-heap hardware block and data structure with 1000 nodes
<address, distance> for the 1000 shortest distances



If Distance < left child, swap left child;
Else, swap right child

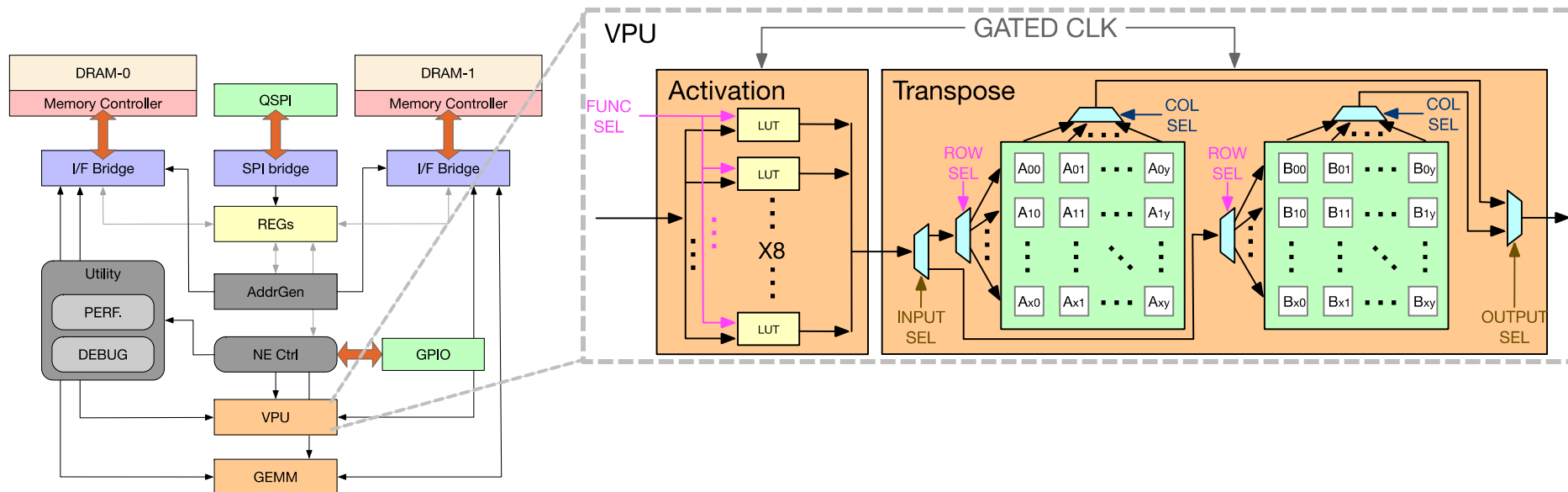
HB-PNM: Neural Engine

- Responsible for similarity prediction for fine-grained ranking



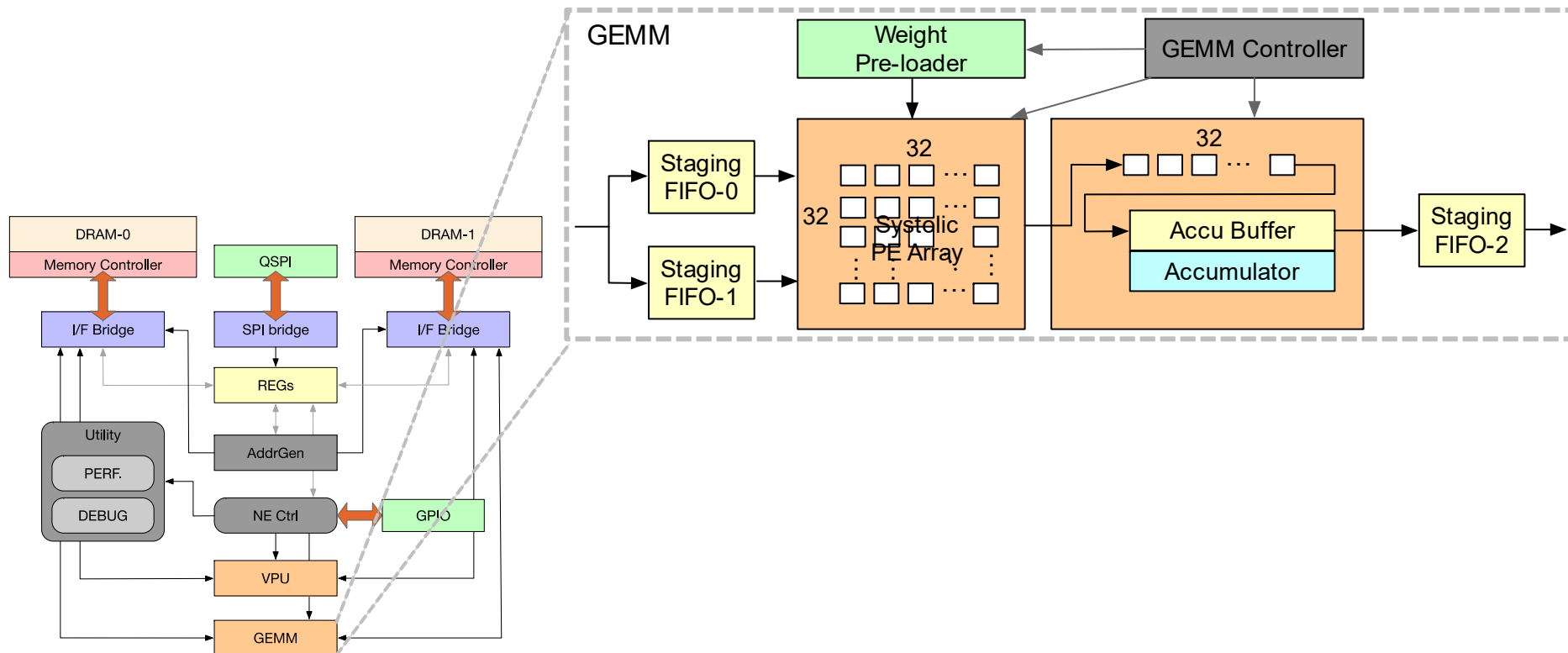
Neural Engine: Vector Processing Unit

- **Activations** based on LUTs
 - ❑ Support for GeLU and Exp
- **Transpose**
 - ❑ Transpose 16x16 matrix with ping-pong array
 - ❑ 2D register file array
 - ❑ Row-based writes and column-based reads



Neural Engine: GEMM

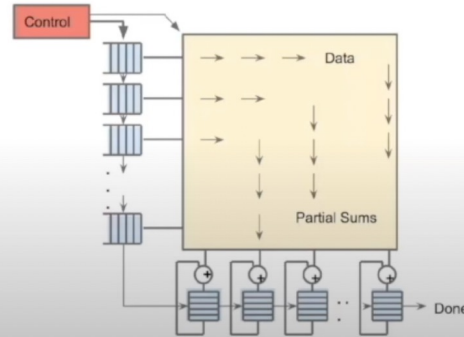
- 32x32 INT8 fully-pipelined **systolic array**
 - Partial sums accumulated in INT32 accumulator



Lecture on Systolic Array Architectures

An Example Modern Systolic Array: TPU (II)

As reading a large SRAM uses much more power than arithmetic, the matrix unit uses systolic execution to save energy by reducing reads and writes of the Unified Buffer [Kun80][Ram91][Ovt15b]. Figure 4 shows that data flows in from the left, and the weights are loaded from the top. A given 256-element multiply-accumulate operation moves through the matrix as a diagonal wavefront. The weights are preloaded, and take effect with the advancing wave alongside the first data of a new block. Control and data are pipelined to give the illusion that the 256 inputs are read at once, and that they instantly update one location of each of 256 accumulators. From a correctness perspective, software is unaware of the systolic nature of the matrix unit, but for performance, it does worry about the latency of the unit.



Jouppi et al., "In-Datacenter Performance Analysis of a Tensor Processing Unit", ISCA 2017.

Digital Design & Computer Arch. - Lecture 19: VLIW and Systolic Array Architectures (Spring 2022)

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Digital Design and Computer Architecture, ETH Zürich, Spring 2022 (
<https://safari.ethz.ch/digitaltechnik..>)

Lecture 19a: VLIW Architectures

Lecture 19b: Systolic Array Architectures

Lecturer: Professor Onur Mutlu (<https://people.inf.ethz.ch/omutlu/>)

Date: May 6, 2022

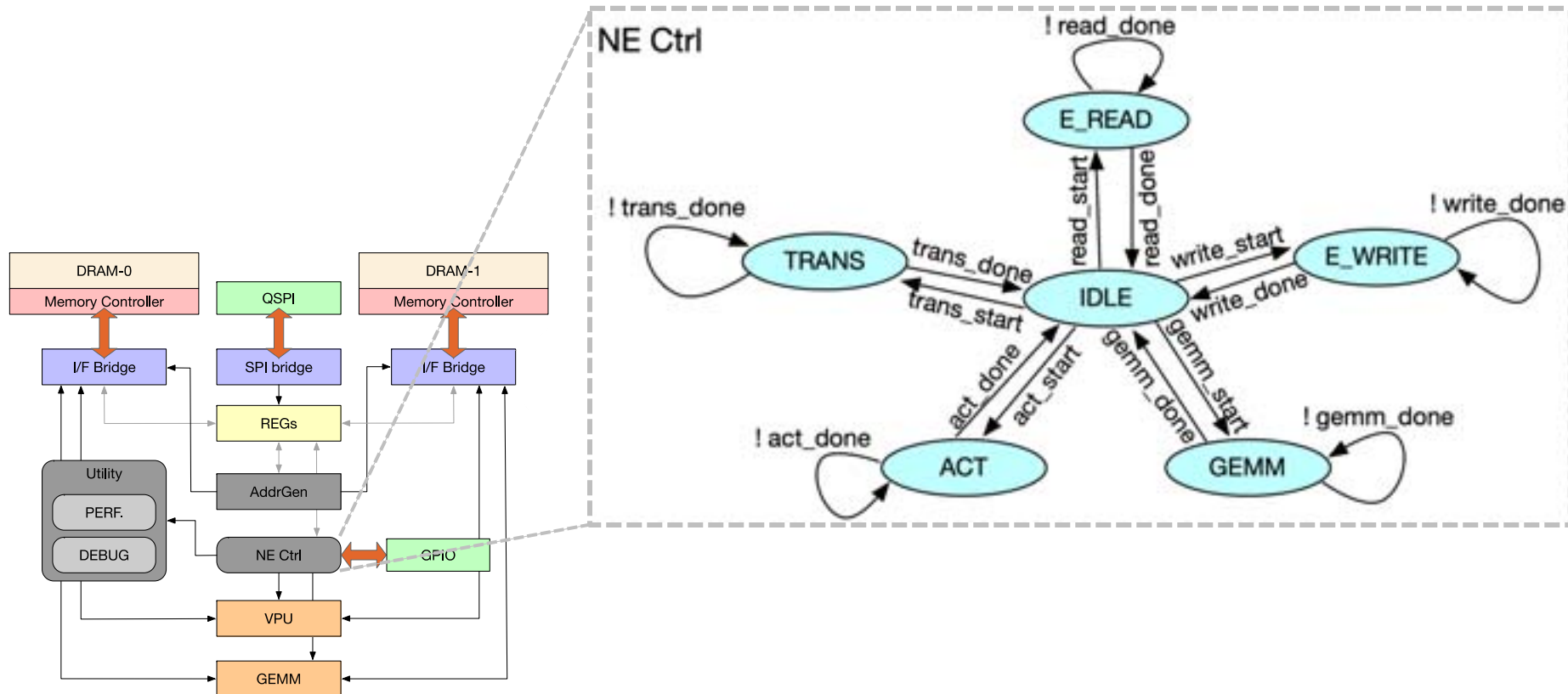
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<https://youtu.be/1SSqV7Y75oU?t=2316>

Neural Engine: Finite State Machine

- Five working states and one idle state
 - Each working state is for one instruction



HB-PNM: Key Feature Summary

■ Comparison table

	2D CIM *	UPMEM PIM **	A100 GPU ***	FIMDRAM ****	This work
Type of Memory	SRAM	DDR4	HBM2	HBM2	LPDDR4
Technology (Memory/Logic)	16nm	2xnm / 2xnm	1y [#] / 7nm	20nm / 20nm	25nm / 55nm
Capacity	4.5 Mb	8GB / DIMM	80GB	6GB / cube	4.5GB
Bandwidth	-	128GB/s / DIMM	1935GB/s	1200GB/s / cube [#]	38.4GB/s / 1Gb
Frequency (Logic)	200MHz	500MHz	1410MHz	300MHz	300MHz
Bandwidth/Capacity (a.u.)	-	16	24.2	200	307
Energy	-	~25pJ/bit	4.47pJ/bit	2.75pJ/bit	0.88pJ/bit

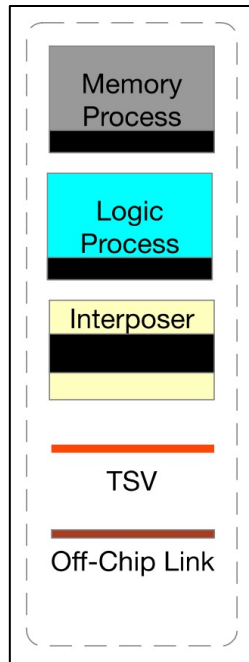
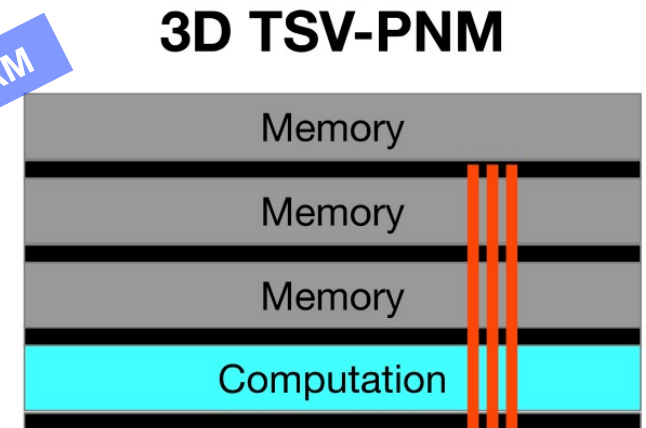
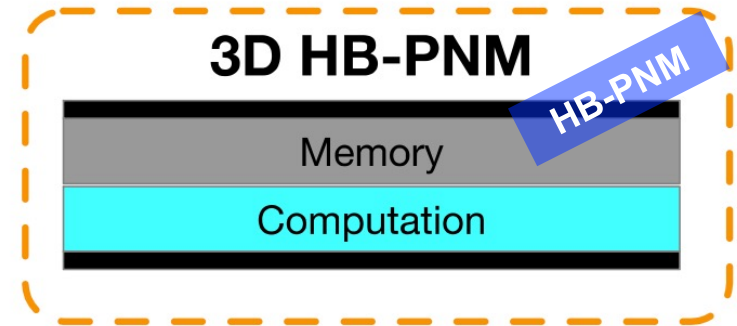
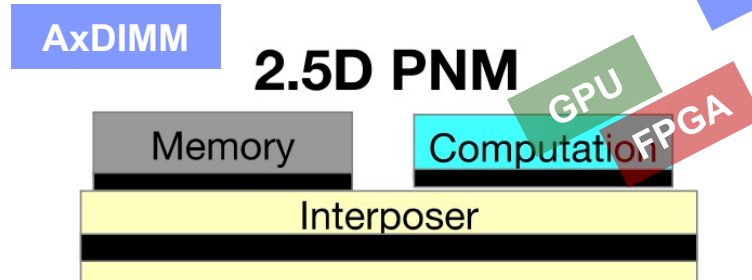
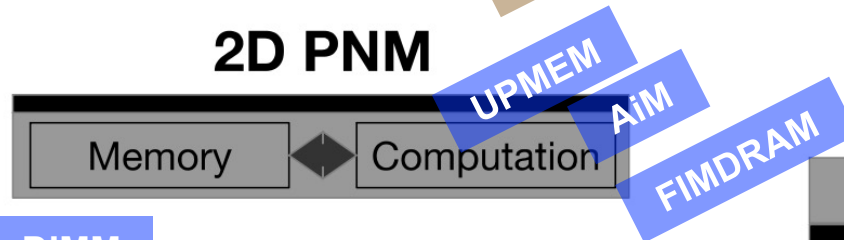
* H. Jia et al, ISSCC 2021.

** F. Devaux et al, Hotchip 2019

*** J. Choquette et al, Hotchip 2020

**** Y. C. Kwon et al, ISSCC 2021

Processing-in-Memory Classification



PNM : Process Near Memory
CIM: Compute In Memory

HB : Hybrid Bonding
TSV: Through-silicon Via

Two PIM Approaches

5.2. Two Approaches: Processing Using Memory (PUM) vs. Processing Near Memory (PNM)

Many recent works take advantage of the memory technology innovations that we discuss in Section 5.1 to enable and implement PIM. We find that these works generally take one of two approaches, which are categorized in Table 1: (1) *processing using memory* or (2) *processing near memory*. We briefly describe each approach here. Sections 6 and 7 will provide example approaches and more detail for both.

Table 1: Summary of enabling technologies for the two approaches to PIM used by recent works. Adapted from [309].

Approach	Enabling Technologies
Processing Using Memory	SRAM
	DRAM
	Phase-change memory (PCM)
	Magnetic RAM (MRAM)
Processing Near Memory	Resistive RAM (RRAM)/memristors
	Logic layers in 3D-stacked memory
	Silicon interposers
	Logic in memory controllers

Processing using memory (PUM) exploits the existing memory architecture and the operational principles of the memory circuitry to enable operations within main memory with minimal changes. PUM makes use

Onur Mutlu, Saugata Ghose, Juan Gomez-Luna, and Rachata Ausavarungnirun,
["A Modern Primer on Processing in Memory"](#)

*Invited Book Chapter in **Emerging Computing: From Devices to Systems - Looking Beyond Moore and Von Neumann**, Springer, to be published in 2021.*
[\[Tutorial Video on "Memory-Centric Computing Systems"](#) (1 hour 51 minutes)]

Similarities and Differences among Current PIM Systems

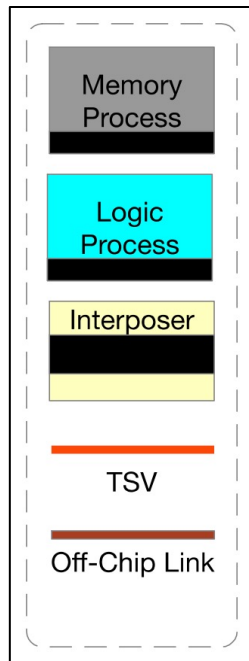
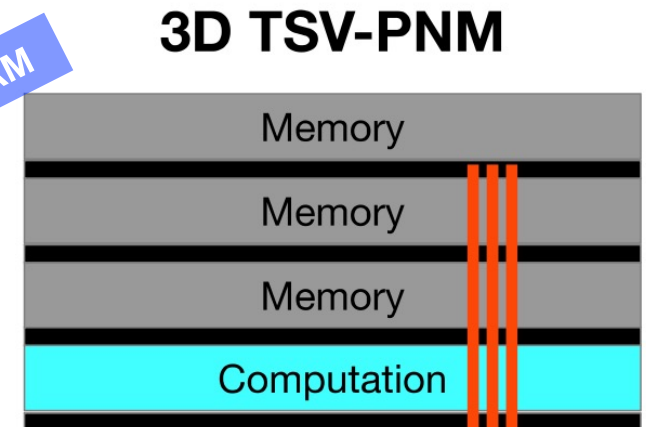
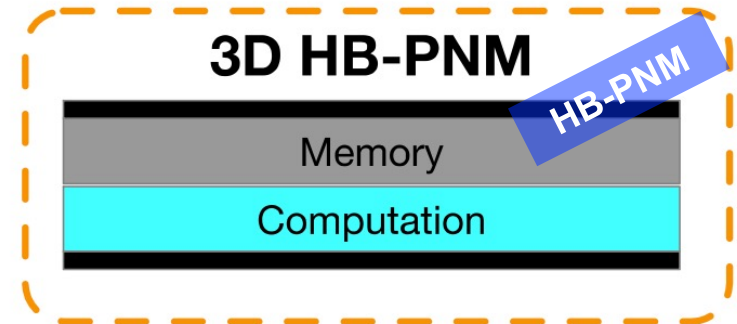
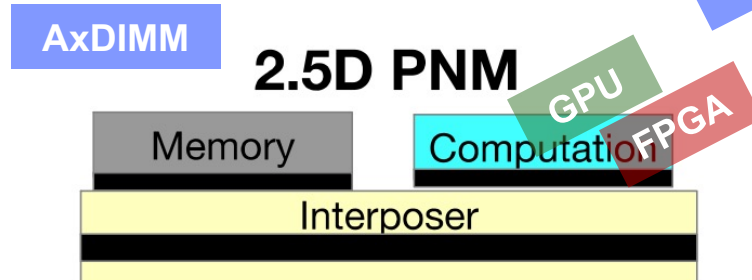
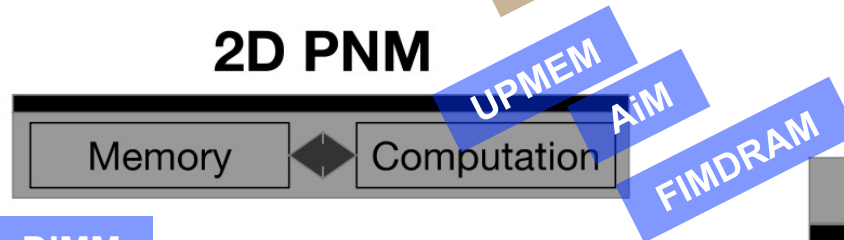
■ Similarities

- ❑ Current real-world processing-in-memory architectures follow a **processing-near-memory** approach
- ❑ All based on DRAM memory

■ Differences

- ❑ Near-bank (UPMEM, FIMDRAM, AiM, HB-PNM) vs. near-chip (AxDIMM)
- ❑ General-purpose (UPMEM) vs. special-function (FIMDRAM, AiM, HB-PNM)
- ❑ FGMT (UPMEM) vs. SIMD (FIMDRAM, AiM, AxDIMM) vs. systolic array (HB-PNM)
- ❑ Natively integer (UPMEM, HB-PNM) vs. floating point (FIMDRAM)
 - FP16 (FIMDRAM) vs. BF16 (AiM) vs. FP32 (AxDIMM)
- ❑ DDR4 (UPMEM, AxDIMM) vs. LPDDR4 (HB-PNM) vs. HBM2 (FIMDRAM) vs. GDDR6 (AiM)

Processing-in-Memory Classification



PNM : Process Near Memory
CIM: Compute In Memory

HB : Hybrid Bonding
TSV: Through-silicon Via

Processing-using-Memory in Real DRAM Chips

ComputeDRAM: In-Memory Compute Using Off-the-Shelf DRAMs

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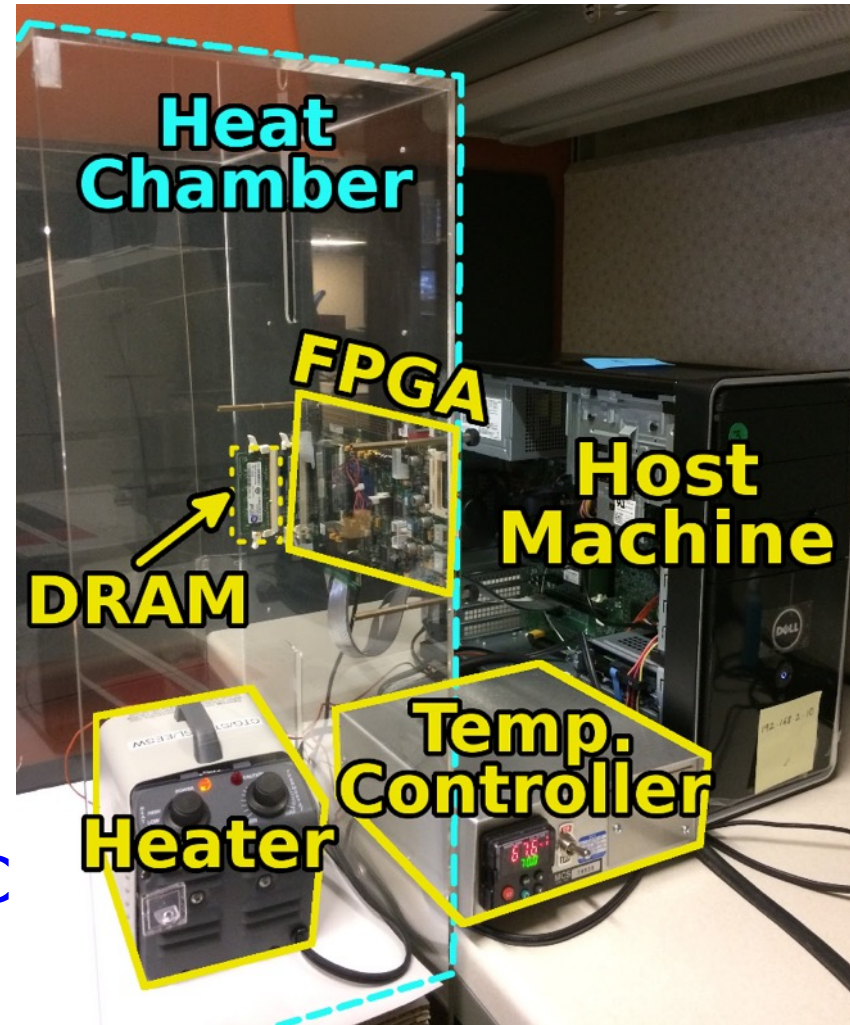
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SoftMC: Open Source DRAM Infrastructure

- Hasan Hassan et al., “[SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies](#),” HPCA 2017
- Flexible
- Easy to Use (C++ API)
- Open-source
github.com/CMU-SAFARI/SoftMC



RowClone & Bitwise Ops in Real DRAM Chips

MICRO-52, October 12–16, 2019, Columbus, OH, USA

Gao et al.

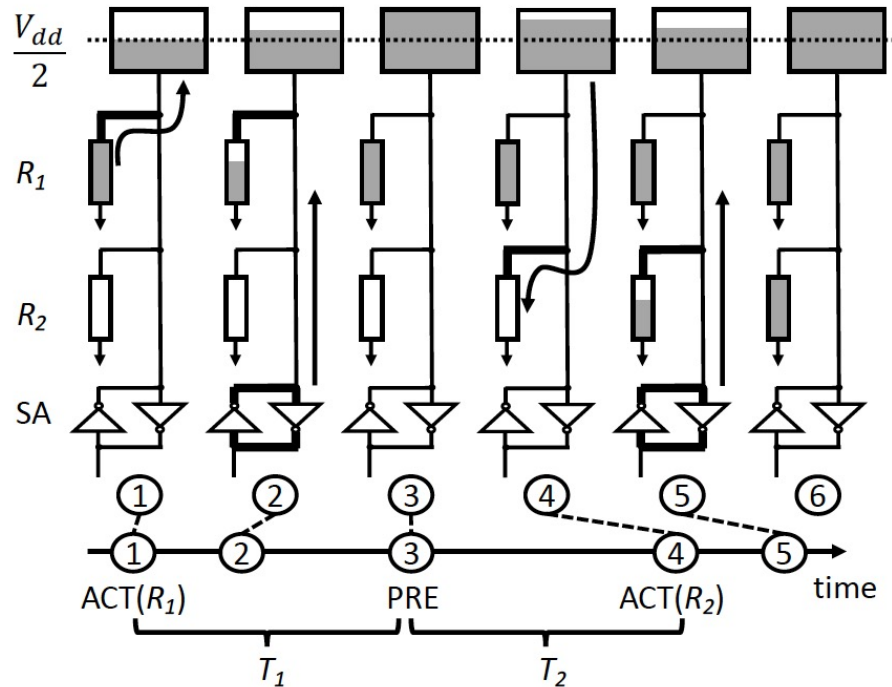


Figure 4: Timeline for a single bit of a column in a row copy operation. The data in R_1 is loaded to the bit-line, and overwrites R_2 .

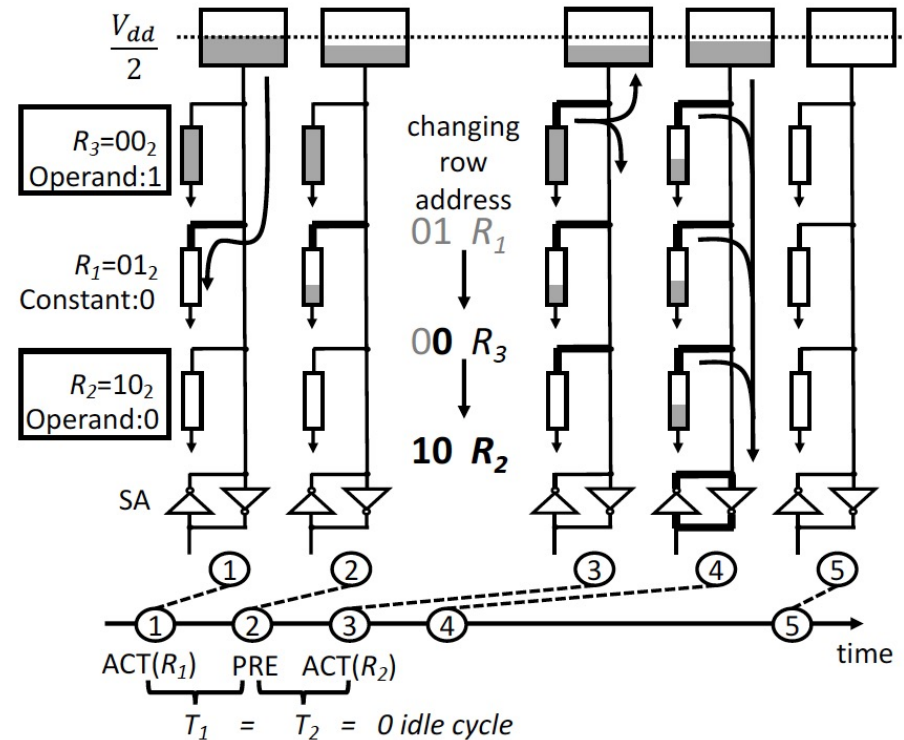
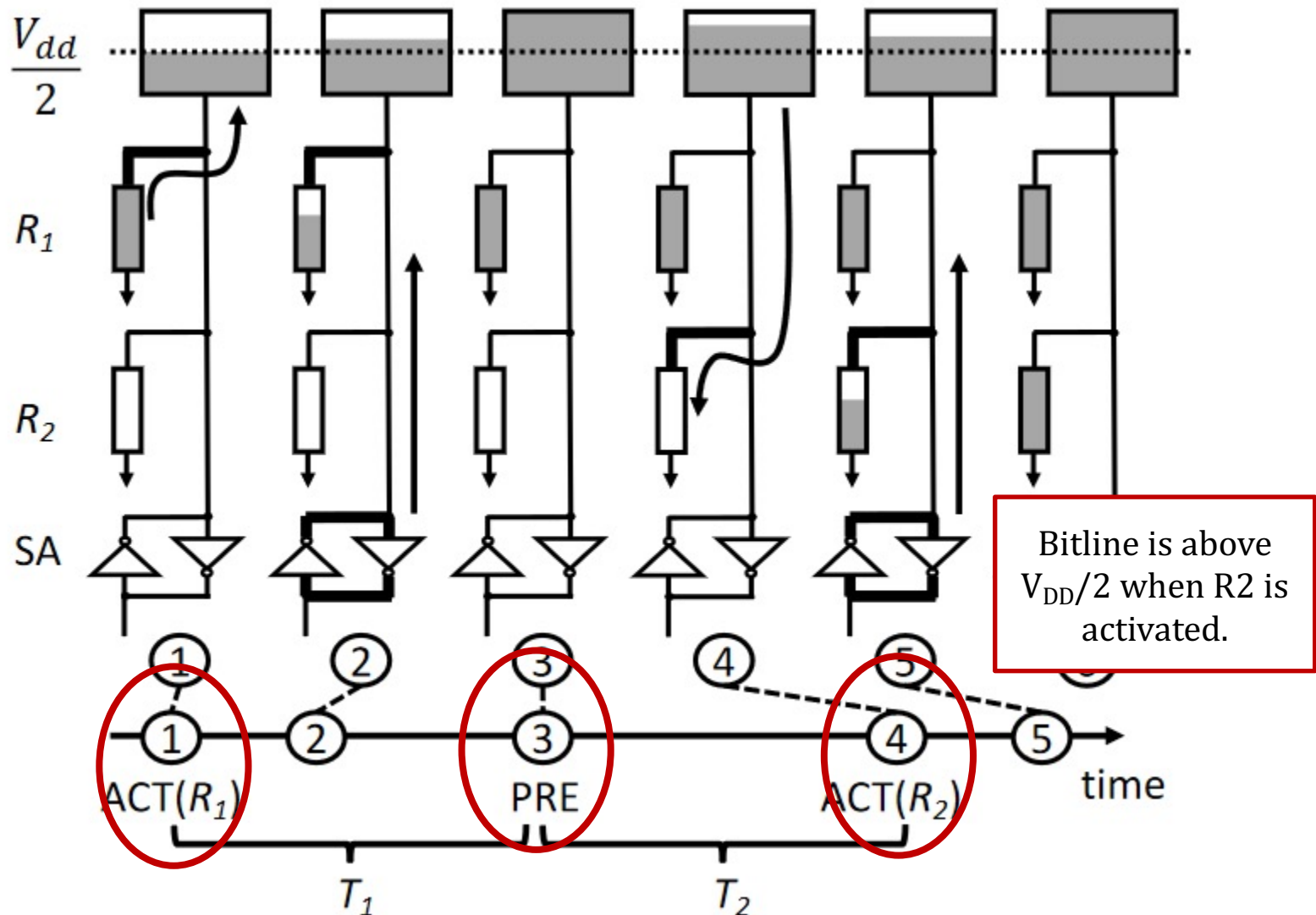
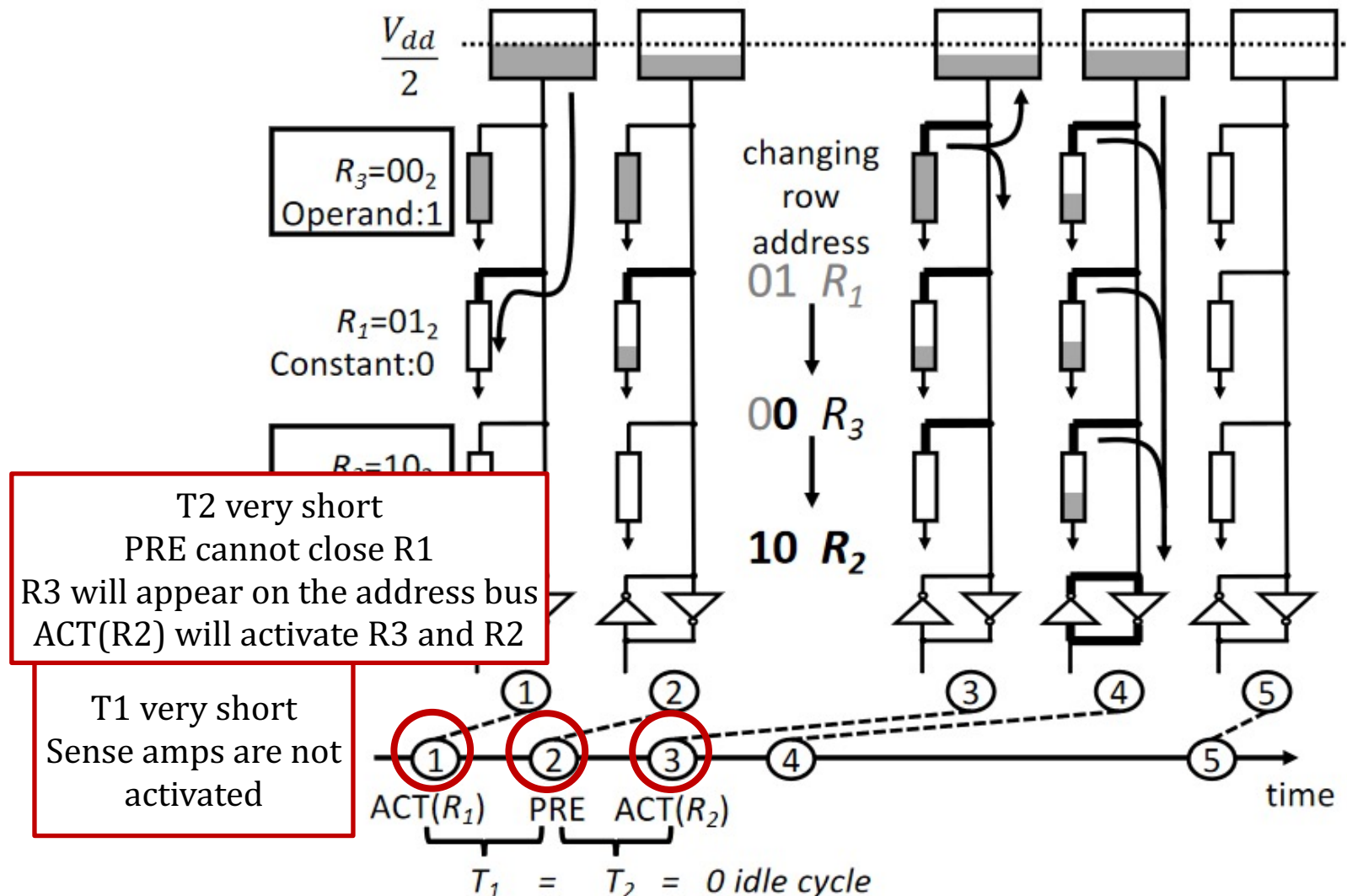


Figure 5: Logical AND in ComputeDRAM. R_1 is loaded with constant zero, and R_2 and R_3 store operands (0 and 1). The result ($0 = 1 \wedge 0$) is finally set in all three rows.

Row Copy in ComputeDRAM



Bitwise AND in ComputeDRAM



Experimental Methodology (I)

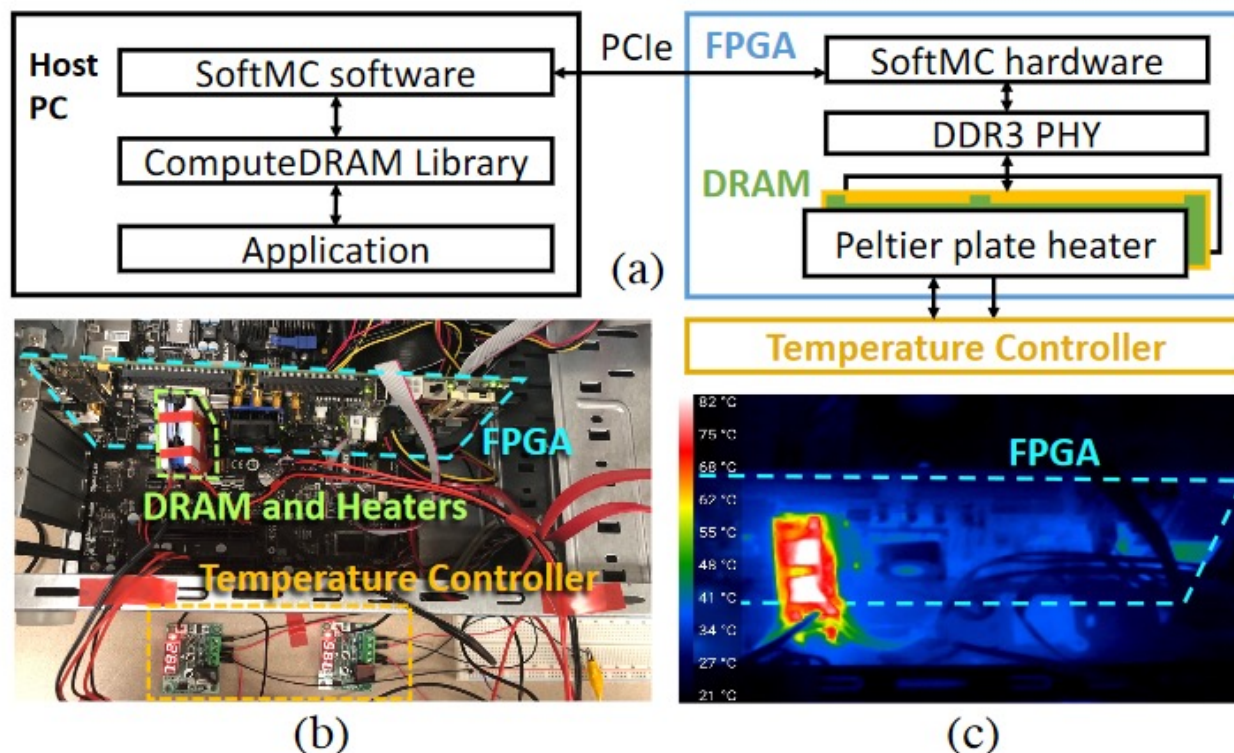


Figure 9: (a) Schematic diagram of our testing framework. (b) Picture of our testbed. (c) Thermal picture when the DRAM is heated to 80 °C.

Experimental Methodology (II)

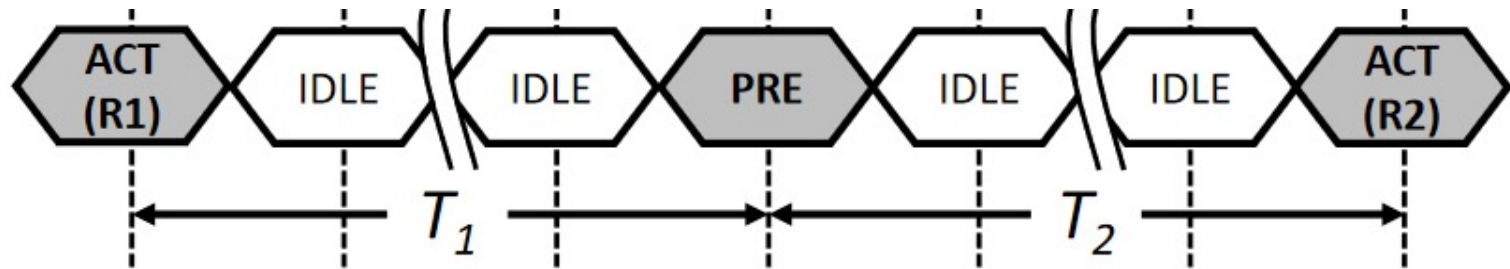
Table 1: Evaluated DRAM modules

Group ID: Vendor_Size_Freq(MHz)	Part Num	# Modules
SKhynix_2G_1333	HMT325S6BFR8C-H9	6
SKhynix_4G_1066	HMT451S6MMP8C-C7	2
SKhynix_4G_1333		2
SKhynix_4G_1333		4
SKhynix_4G_1333		2
Samsung_4G_1333		2
Samsung_4G_1333		2
Micron_2G_1333		2
Micron_2G_1333		2
Elpida_2G_1333	EBJ21UE8BDS0-DJ-F	2
Nanya_4G_1333	NT4GC64B8HG0NS-CG	2
TimeTec_4G_1333	78AP10NUS2R2-4G	2
Corsair_4G_1333	CMSA8GX3M2A1333C9	2

32 DDR3 Modules
~256 DRAM Chips

Proof of Concept (I)

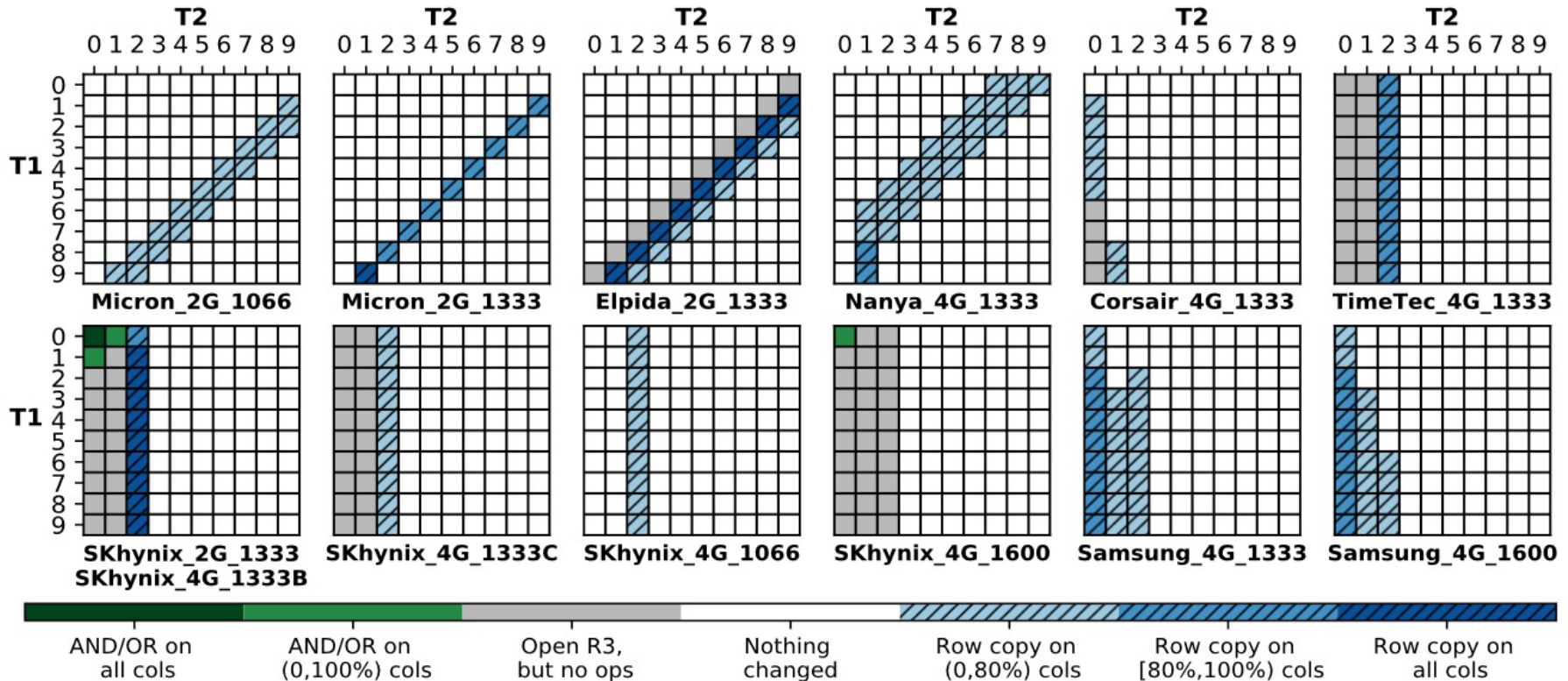
- How they test these memory modules:
 - Vary T_1 and T_2 , observe what happens.



SoftMC Experiment

1. Select a random subarray
2. Fill subarray with random data
3. Issue ACT-PRE-ACTs with given T_1 & T_2
4. Read out subarray
5. Find out how many columns in a row support either operation
 - Row-wise success ratio

Proof of Concept (II)



- Each grid represents the success ratio of operations for a specific DDR3 module.

Processing-using-Memory in Real DRAM Chips

ComputeDRAM: In-Memory Compute Using Off-the-Shelf DRAMs

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PnM and PuM Working Synergistically

- Maciej Besta, Raghavendra Kanakagiri, Grzegorz Kwasniewski, Rachata Ausavarungnirun, Jakub Beránek, Konstantinos Kanellopoulos, Kacper Janda, Zur Vonarburg-Shmaria, Lukas Gianinazzi, Ioana Stefan, Juan Gómez-Luna, Marcin Copik, Lukas Kapp-Schwoerer, Salvatore Di Girolamo, Nils Blach, Marek Konieczny, Onur Mutlu, and Torsten Hoefler, **"SISA: Set-Centric Instruction Set Architecture for Graph Mining on Processing-in-Memory Systems"**
Proceedings of the 54th International Symposium on Microarchitecture (MICRO), Virtual, October 2021. [[Older arXiv version](#)]

SISA: Set-Centric Instruction Set Architecture for Graph Mining on Processing-in-Memory Systems

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Upcoming Lectures

- PUM architectures and prototypes
- Case studies
 - SpMV on UPMEM PIM architecture
 - Neural network accelerators for the edge
 - Hybrid transactional and analytical processing (HTAP) databases
- Enabling the adoption of PIM

P&S Processing-in-Memory

Real-World Processing-in-Memory Architectures:
Alibaba Hybrid Bonding PNM Engine

Dr. Juan Gómez Luna

Prof. Onur Mutlu

ETH Zürich

Fall 2022

29 November 2022